

Quantum Transport FS 2015

lecture given in spring 2015 by:



Christian Schönenberger

Dominik Zumbühl

Andreas Baumgartner

Markus Weiss

lecture is on Tuesdays 16:15 – 18:00

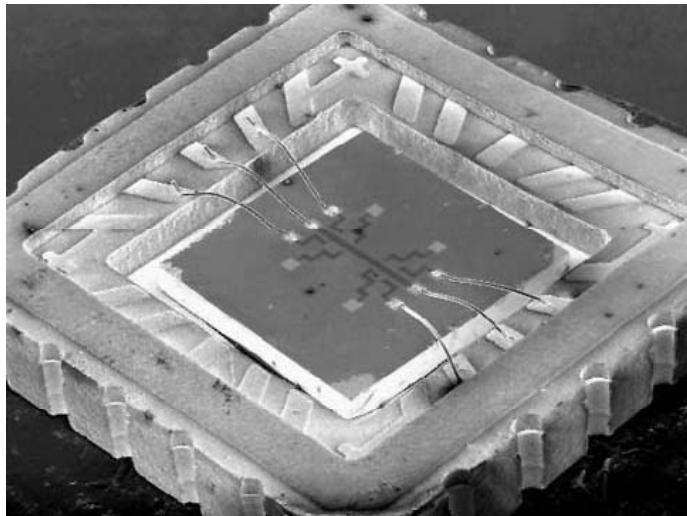
exercises are on Thursdays from 10:15 till 12:00

you must attend the exercises if you want to get the credit points
in the last exercise we will make a written test

condition for credits: pass the test and have attended 80% of the exercise classes

all in English

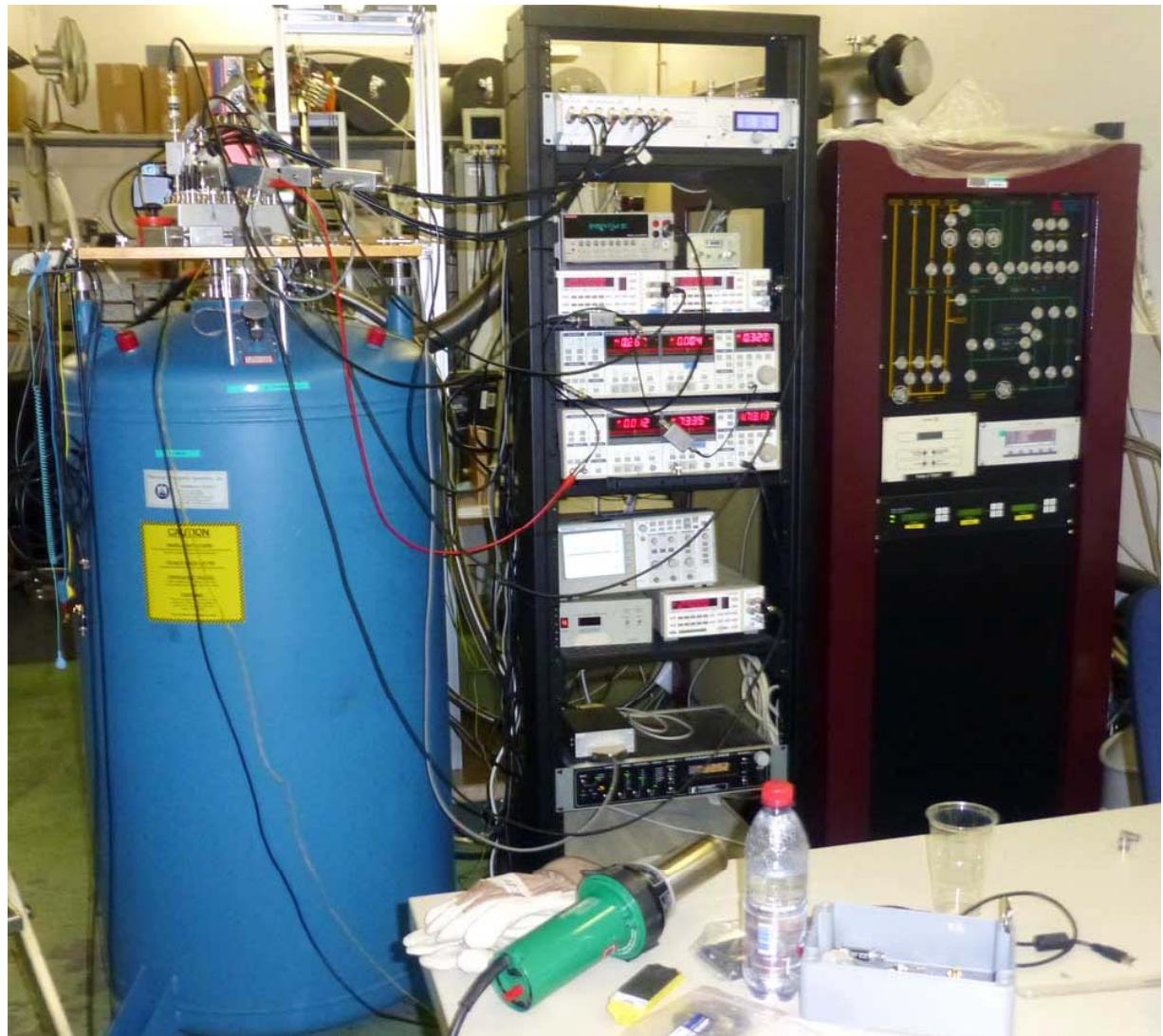
1. Quantum Transport / Introduction



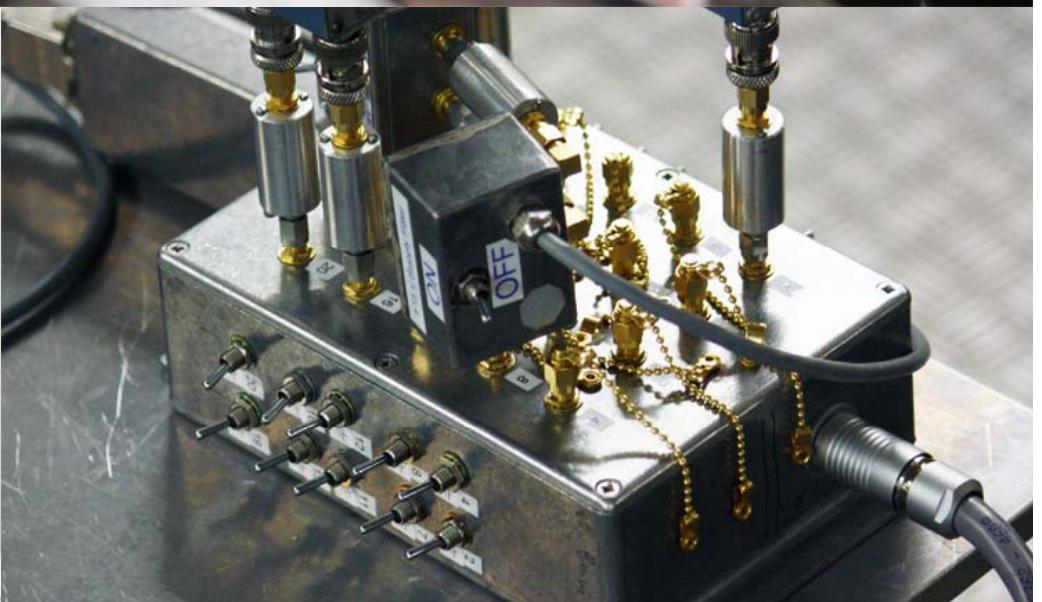
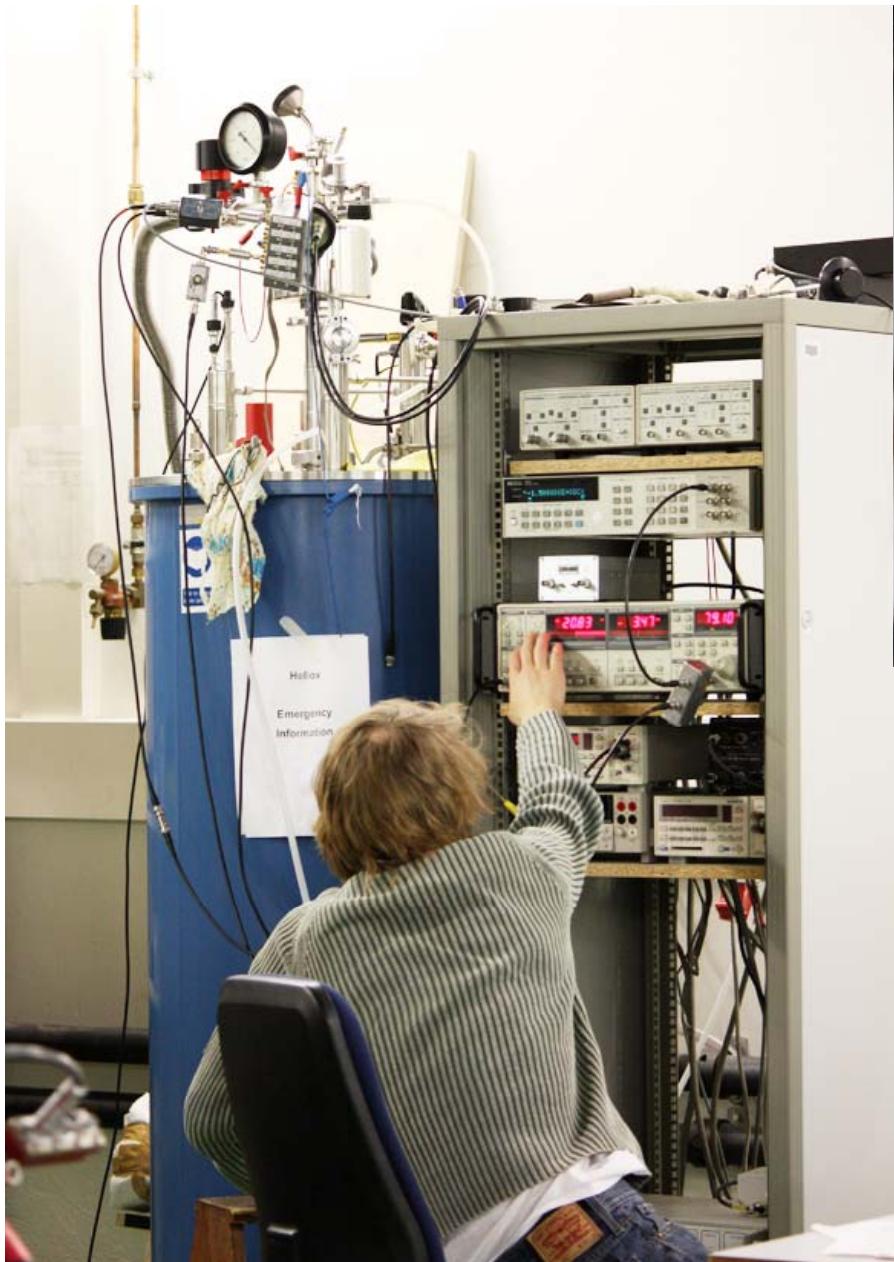
a chip carrier with a “sample”
connected by bonding wires

usually fabricated by
lithography methods

often measured in a cryostat
measurements mostly electrics, but other degrees
also of interest (e.g. photons)



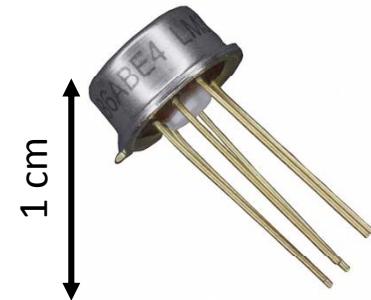
1. Intro / Measurement techniques



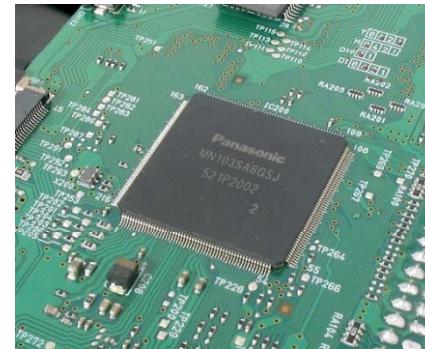
1. Intro / Motivation / history



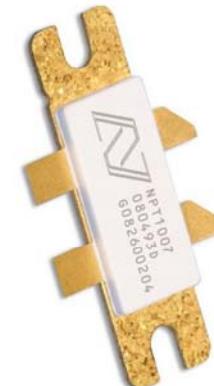
Si transistor



„Chip“ integrated circuits



GHz
electronics



stereo and
TV for all



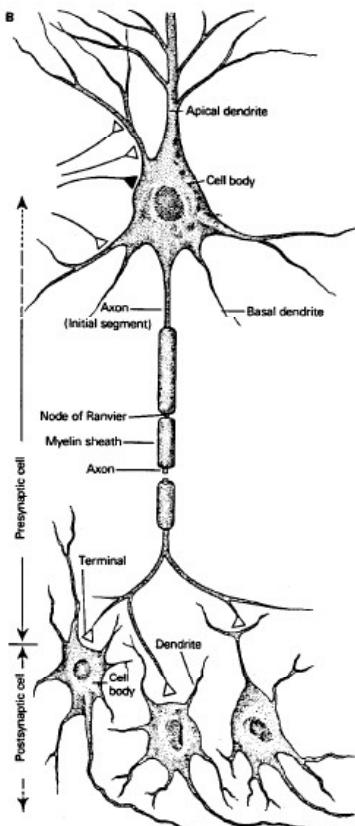
bits und bytes
PC / internet for all



online at
all times

1. Intro / Bioelectronics

Biochip: „brain on a chip“ DNA memory

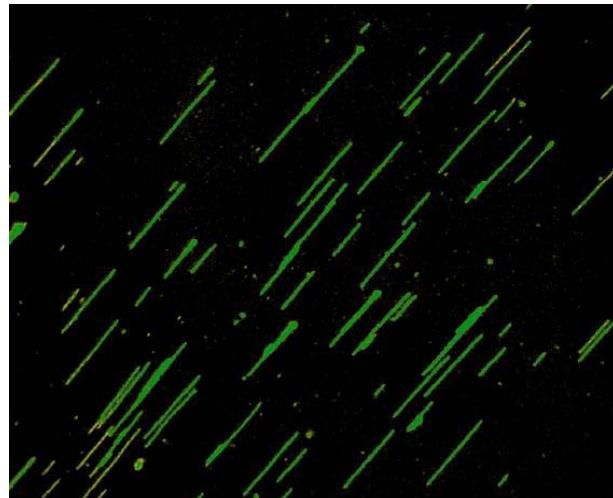


Brain, neural networks, and computation
J. J. Hopfield

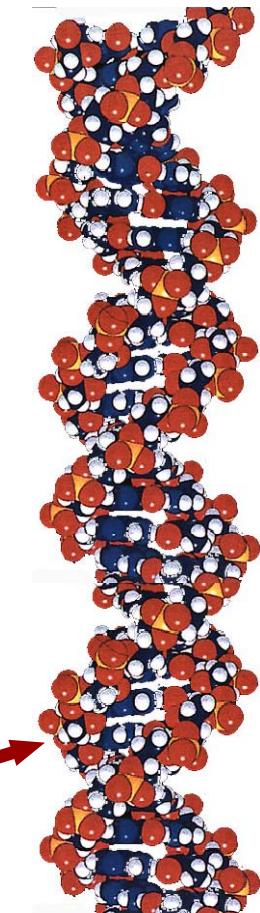


neurons on a chip

image of DNA



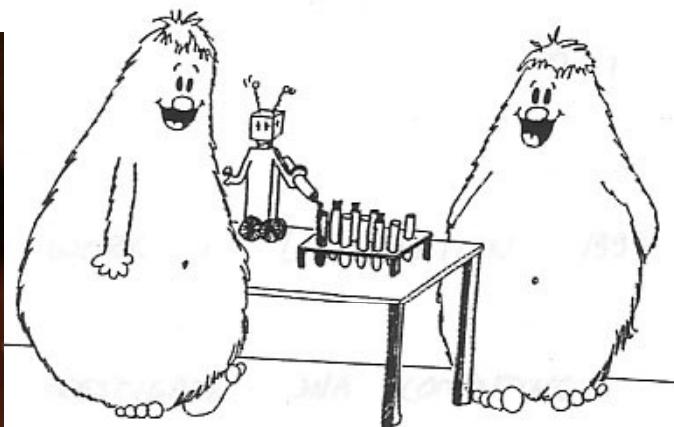
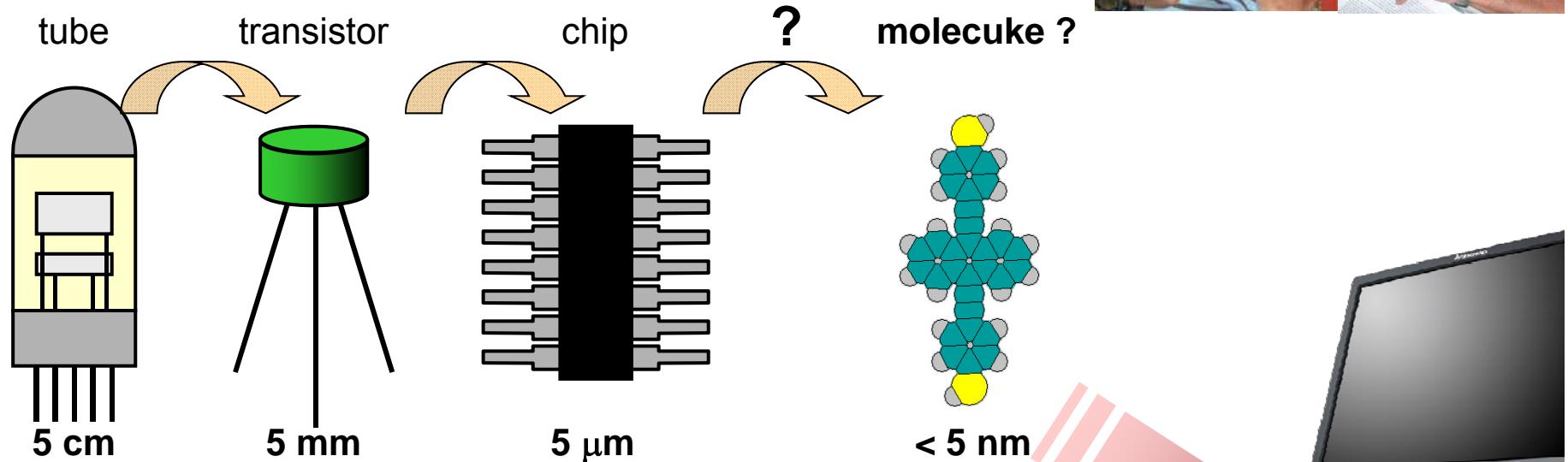
Erbsubstanzmoleküle



1. Intro / Molecular Electronics

Marcel Mayor (Chemie), Michel Calame (Physik)

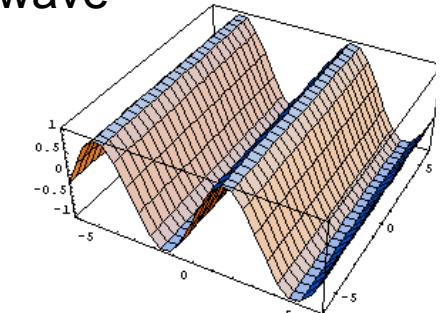
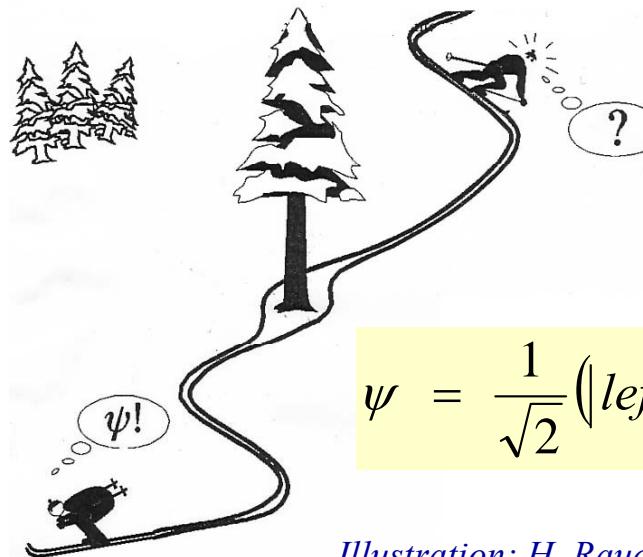
molecular electronics: the computer in a test tube



1. Intro / Quantum electronics



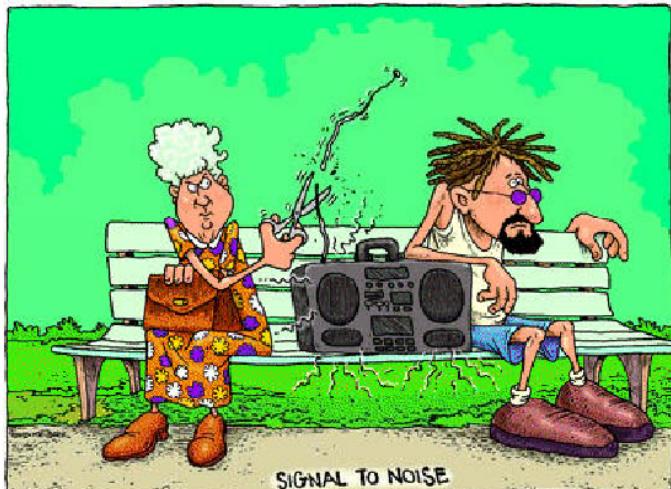
the electron is a **quantum particle**, it can behave as a wave and therefore interfere :



quantum effect

$$\psi = \frac{1}{\sqrt{2}}(|left\rangle + |right\rangle)$$

Illustration: H. Rauch ATI, Wien



quantum physics delivers concepts for a new way of computing → **quantum computing**

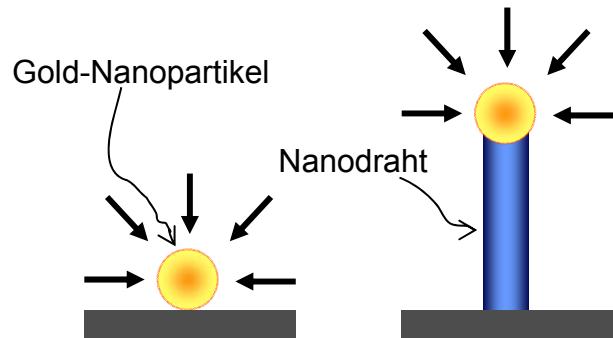
„The weirdest computer of all“ (The Economist)

1. Technology plays a crucial role (but not only)

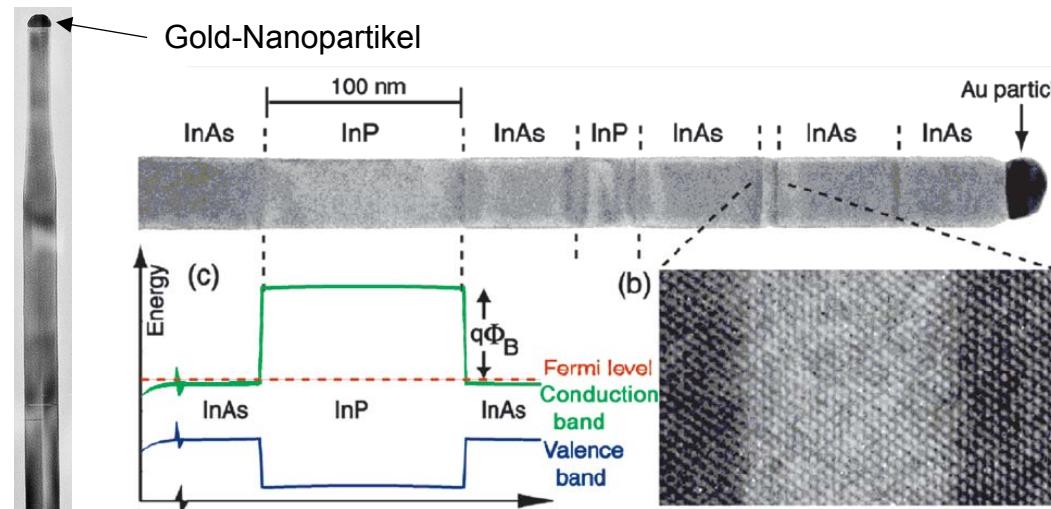
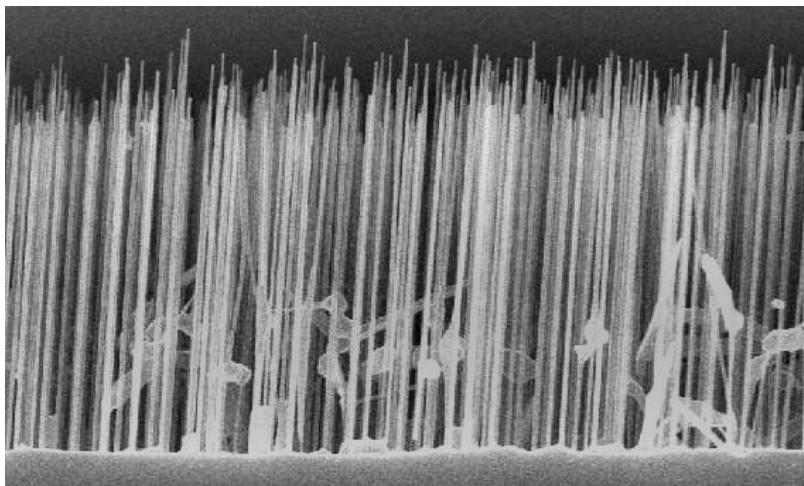
- **fabrication technology** (devices need to be made)
- devices get smaller and **smaller**
- signals get also smaller and **faster** and there is much more data
- **imaging** and analytics important
- engineering, physics, chemistry and biology may come together → **language problem**
- **new materials** may also give the field a decisive push

for example: nanowires

gold nanoparticles are used to catalyze the growth of nanowires



diameter \sim 10-50 nm



aus: M.T. Björk et al., *Nano Lett.* 2, 87 (2002)

composition can be changed during growth



Jesper Nygård (Copenhagen)



Szabolcs Csonka (Budapest)

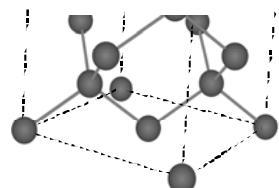


Lukas Hofstetter (Basel)

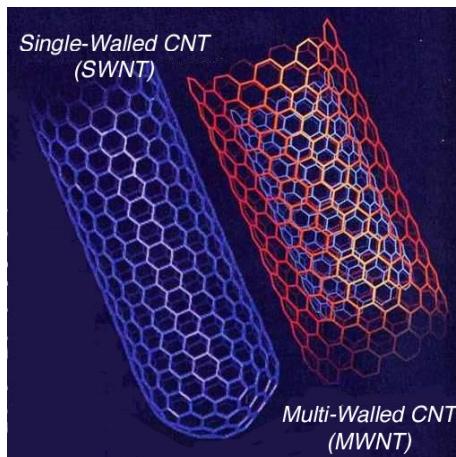
Carbon materials

Diamond (sp^3 carbon):

- hard material
- very good electrical insulator, but still a very good heat conductor
(why?)

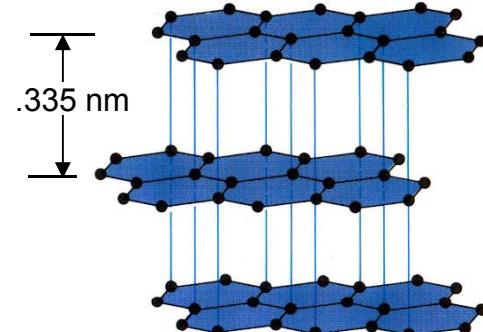


6	12.011
4470	$\pm 4,2$
4100	
2.62	
$1s^2 2s^2 p^2$	
Carbon	



Nanotubes:

metallic and semiconducting ones:
diameter 0.5 - 50 nm



Graphite (sp^2 Carbon):

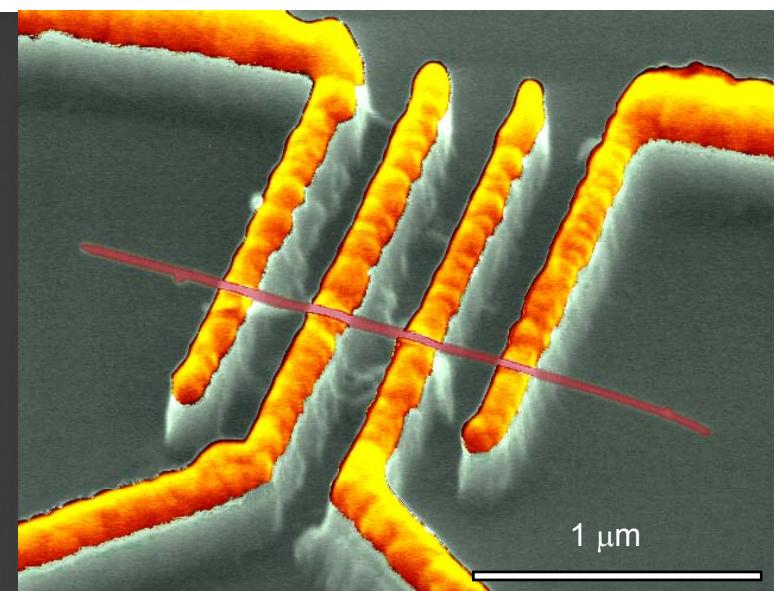
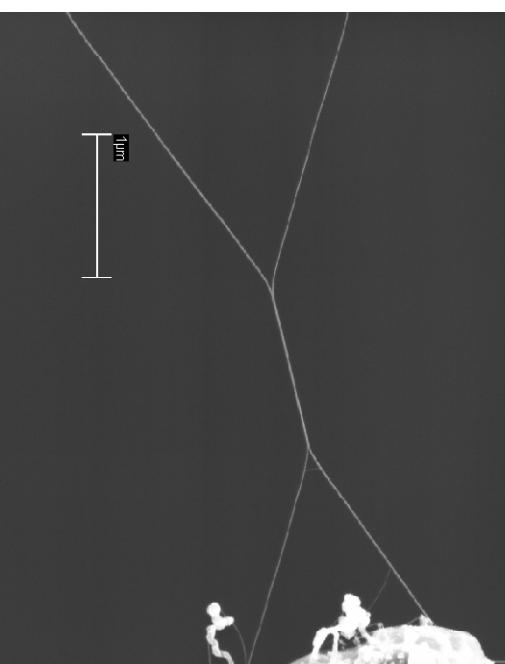
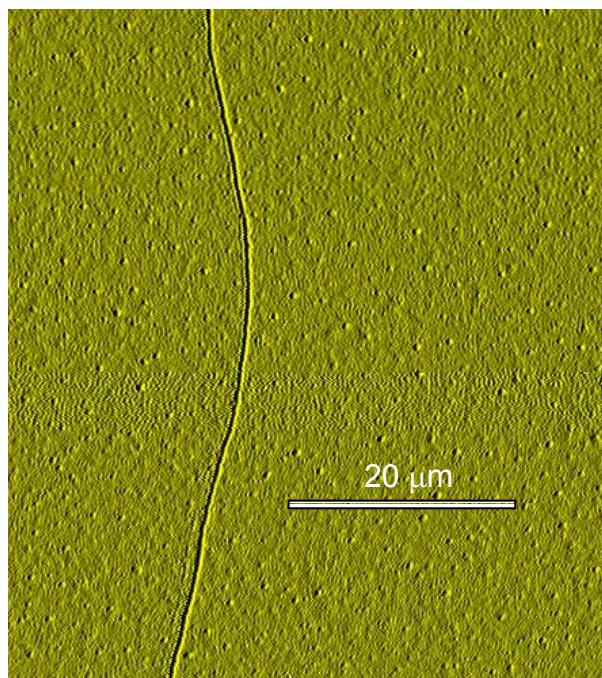
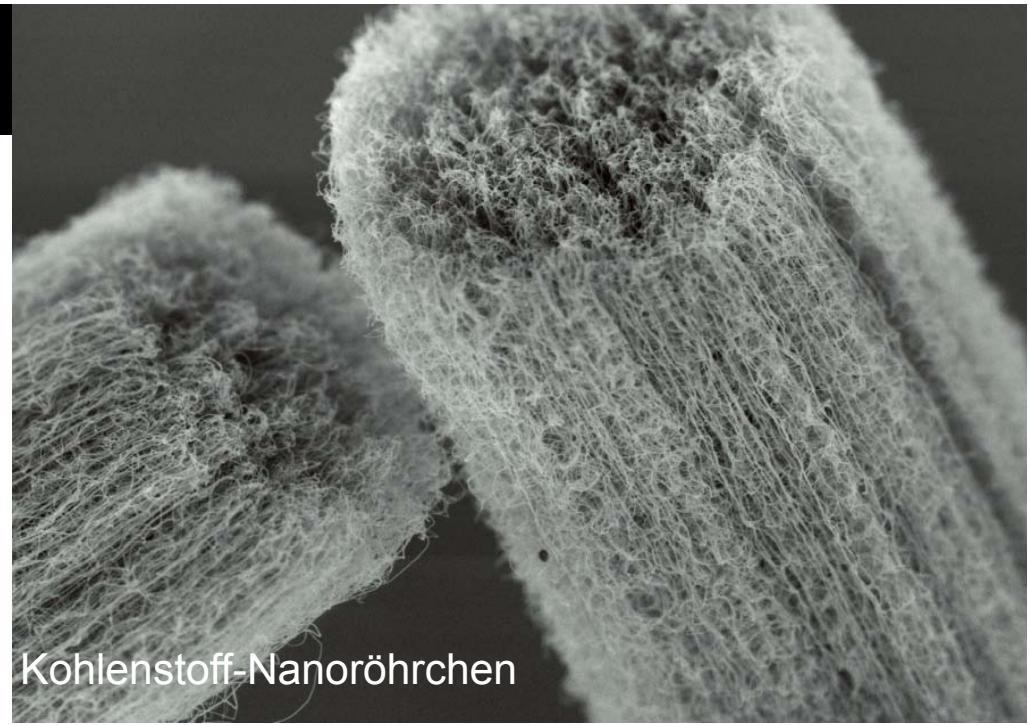
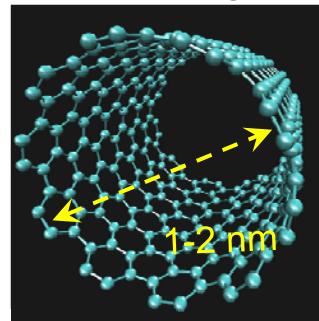
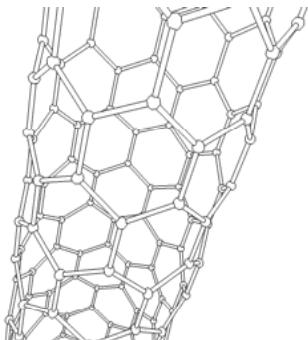
- simple to write with (pencil)
- good electrical conductor

Fullerene (C_{60}):
diameter = 0.7 nm

Carbon Nanotubes



...new forms of graphite



Carbon Nanotubes

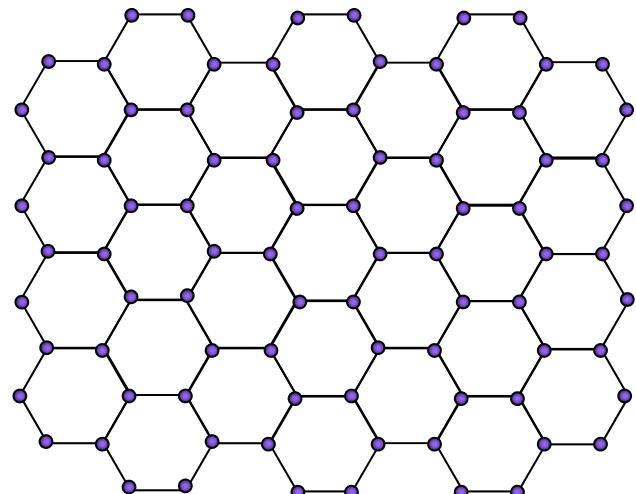


Mit Carbon Nanoröhrchen lassen sich auch ultraleichte und ultrafeste Komposite herstellen, z.B. für Fahrräder, Boeing und Airbus

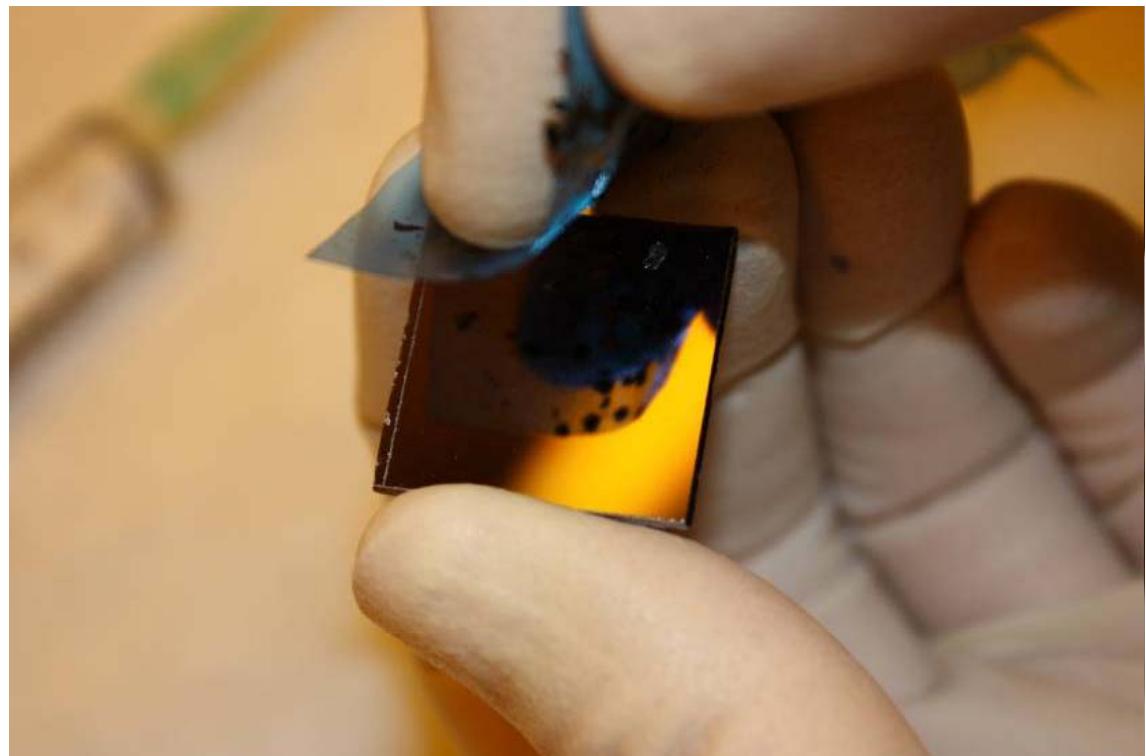
Graphene



graphite is separated with a Scotch
tape into it separate thinner layers



„Graphene“ = Kohlenstoff-
Monoschicht



in graphene, electrons behave in a way like relativistic massless particles

Micro- and Nanofabrication



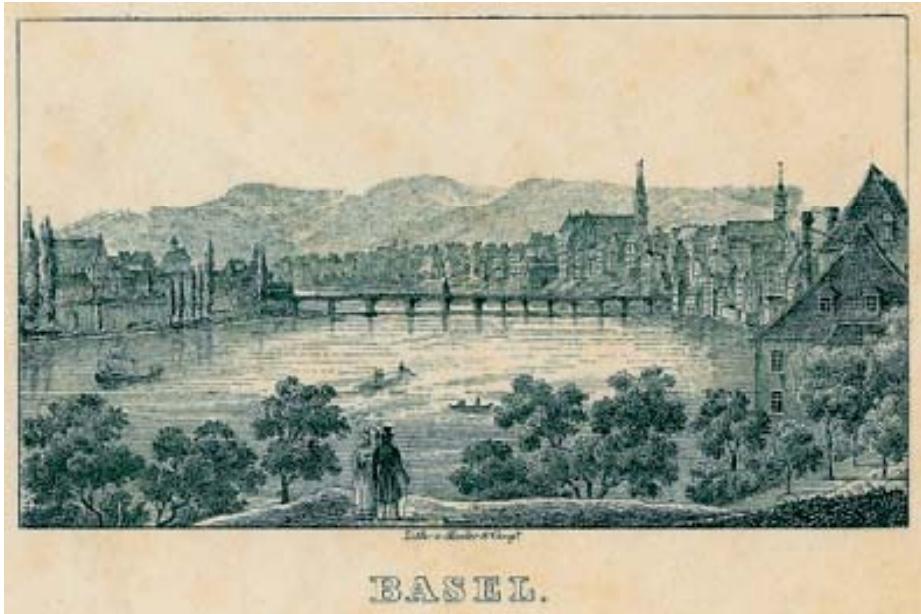
copyright 1997 philg@mit.edu

copyright 1997 philg@mit.edu

1. Intro / Micro- and Nanofabrication Facility



How does it work: lithography

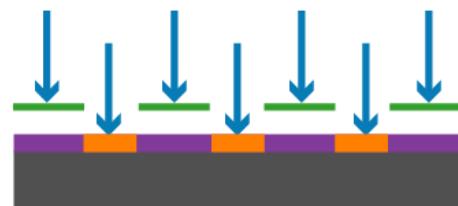


Lithographie von Basel. Druck über eine von Hand vorgezeichnete und danach geätzte Steinplatte

1. resist on silicon



2. expose, e.g. through mask



3. develop



4. metalization

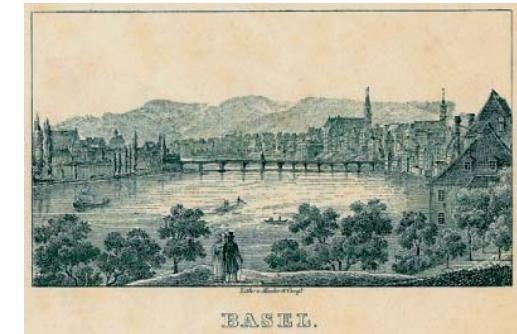


5. lift-off (resist removal)



Lithography for devices

Schönenberger group www.nanoelectronics.ch



Lithographie von Basel
Druck über eine von Hand vorgezeichnete und danach geätzte Steinplatte



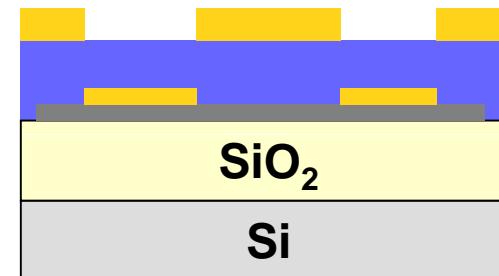
Lithographie mit Licht



... und mit einem Elektronenstrahl



fertig !



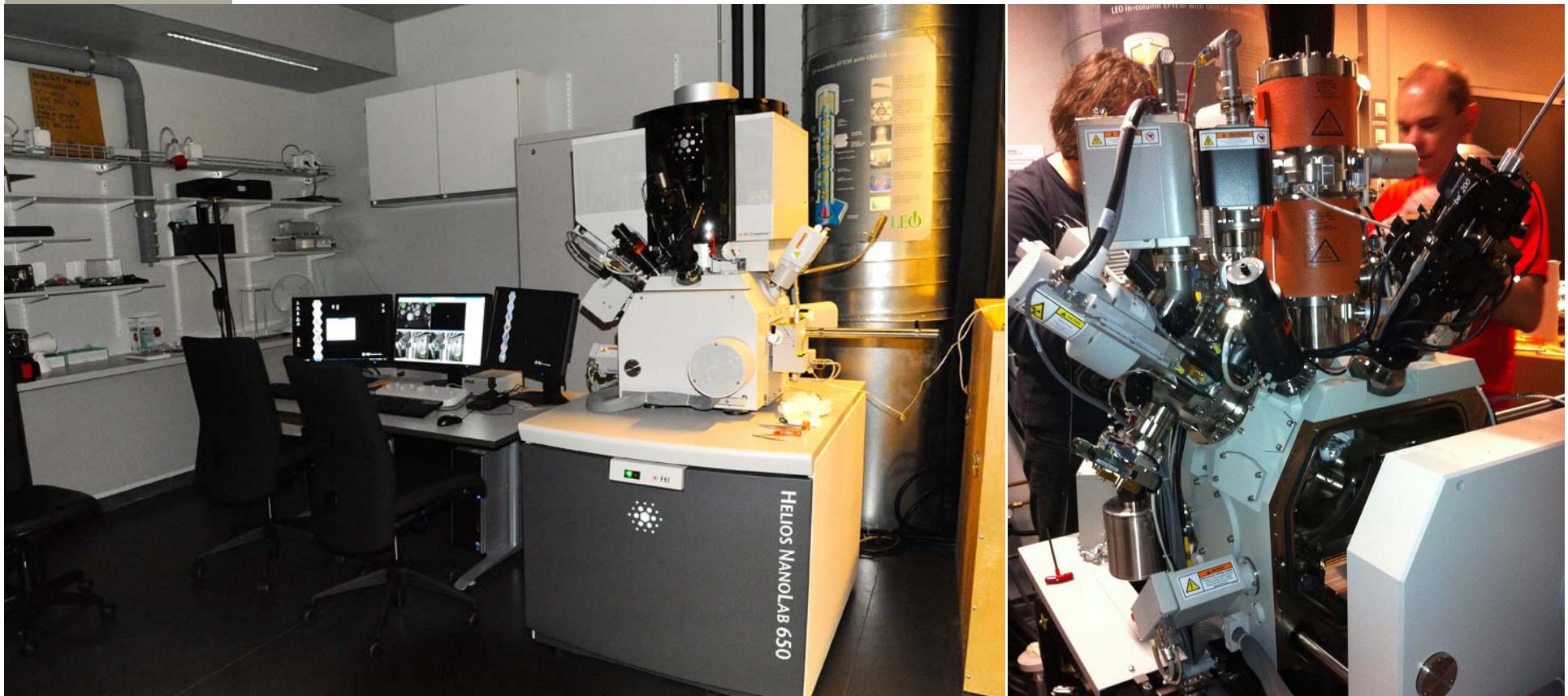
Moderne Lithographie erlaubt uns, Strukturen im Bereich **weniger Nanometer** herzustellen. Hundertfache Wiederholung führt zu einem Pentium Chip.

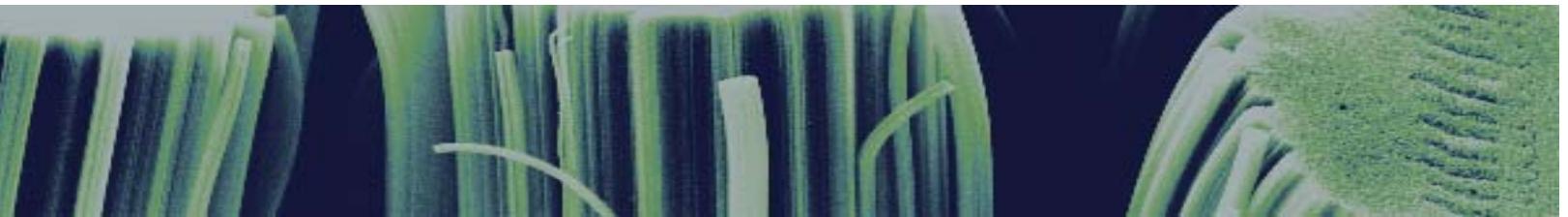


Focused Ion Beam (FIB) together with ZMB

operated as a shared facility by ZMB staff and located at the ZMB

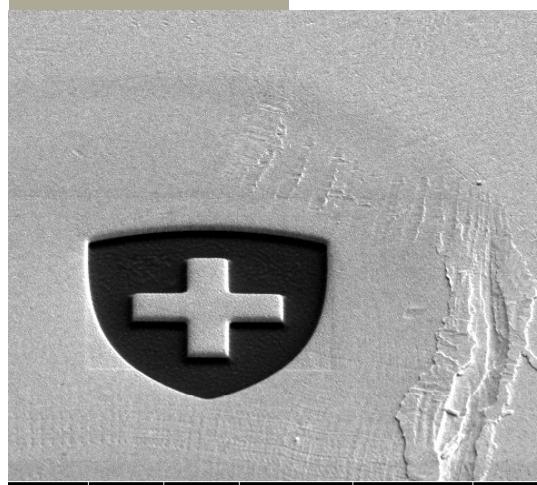
current users are: ZMB, Poggio, Schönenberger, Constable, Gerber, Stahlberg,
Hierlemann (D-BSSE), Lim, Maletinsky, Meyer, Richter



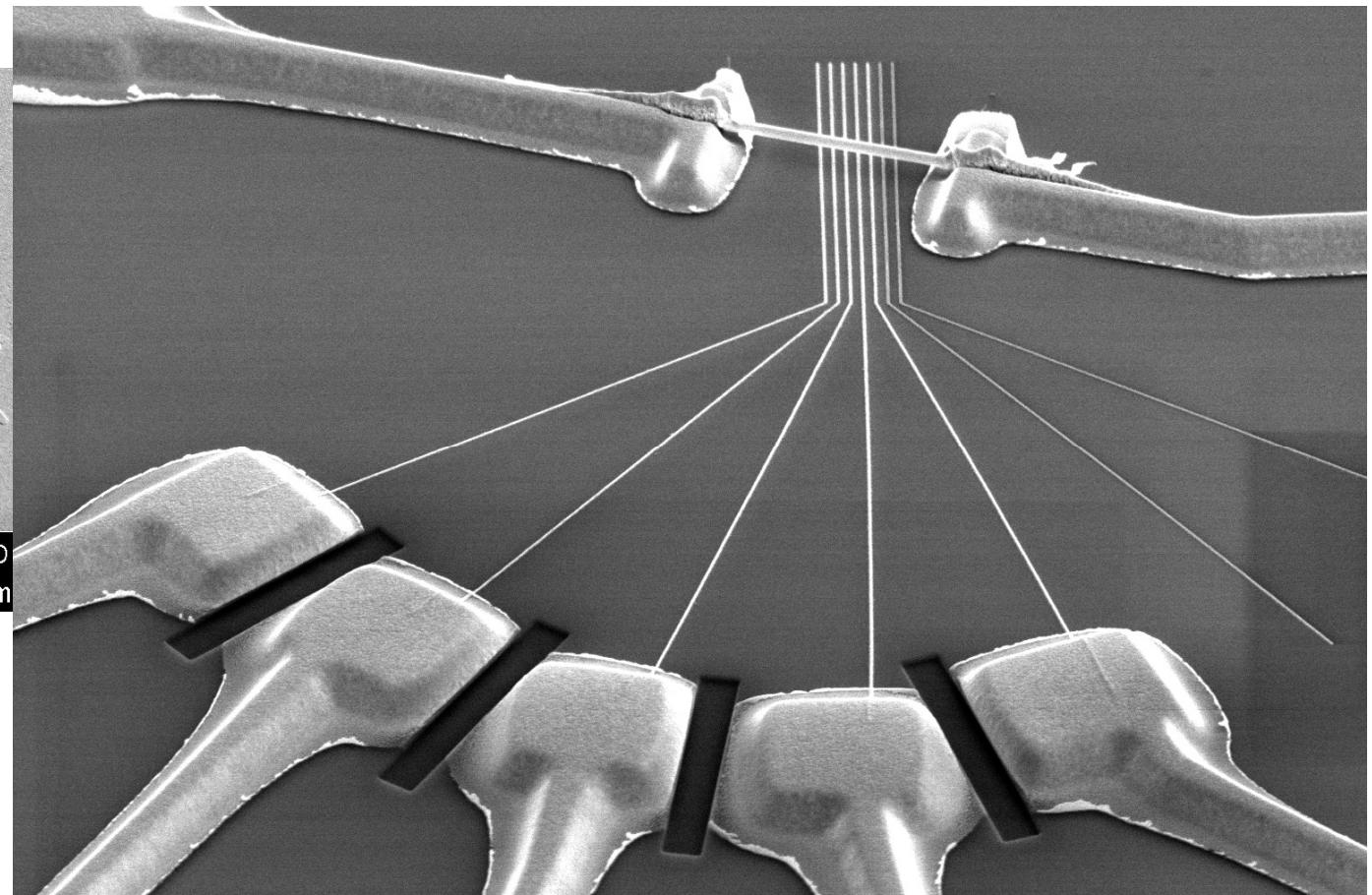
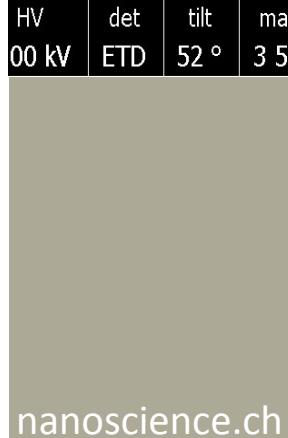


Focused Ion Beam (FIB) together with ZMB

Poggio lab

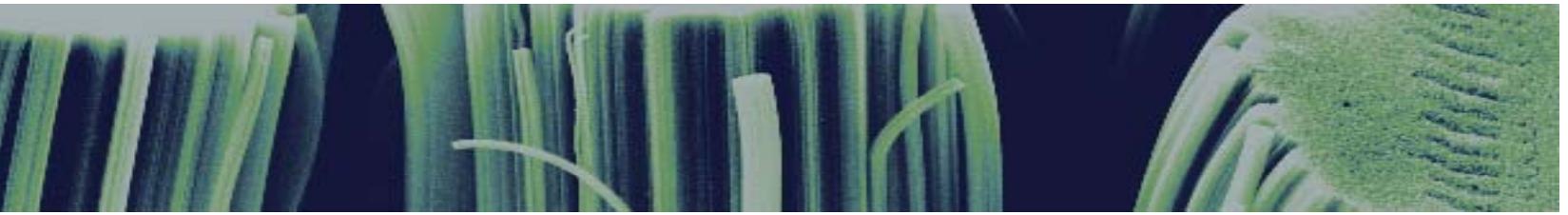


HV det tilt mag HFW WD
00 kV ETD 52 ° 3 500 x 59.2 µm 5.6 m



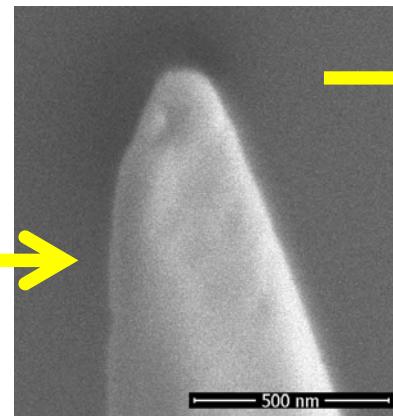
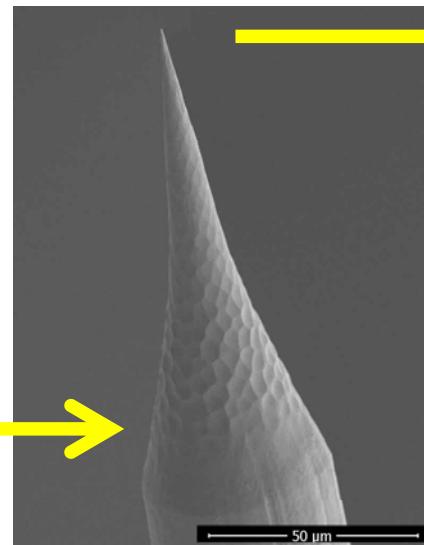
2/18/2013 HV curr dwell det mode tilt mag WD
6:56:27 PM 5.00 kV 25 pA 30 µs ETD SE 52 ° 11 004 x 4.1 mm
4 µm
FEI Helios NanoLab 650

nanoscience.ch

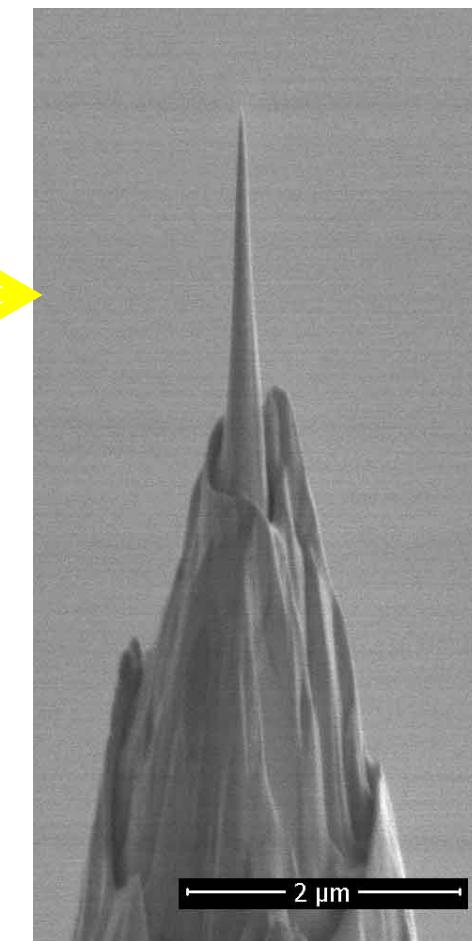


Focused Ion Beam (FIB) together with ZMB

Ernst Meyer lab

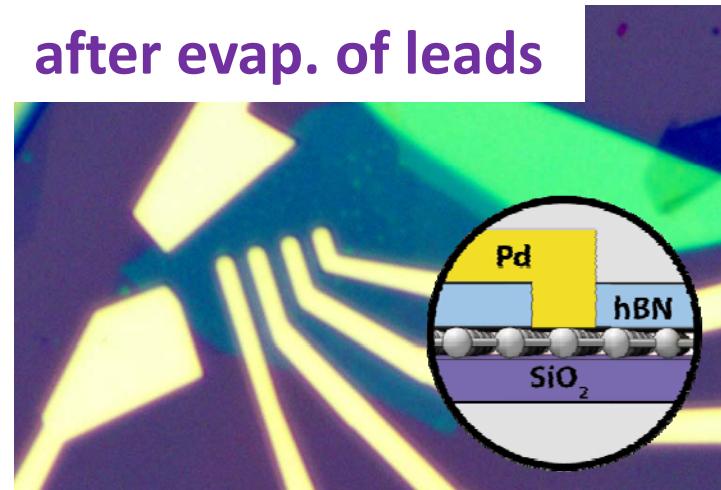
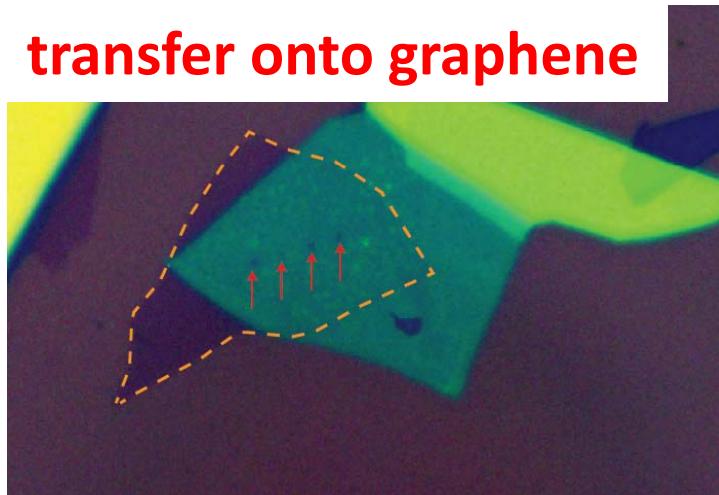
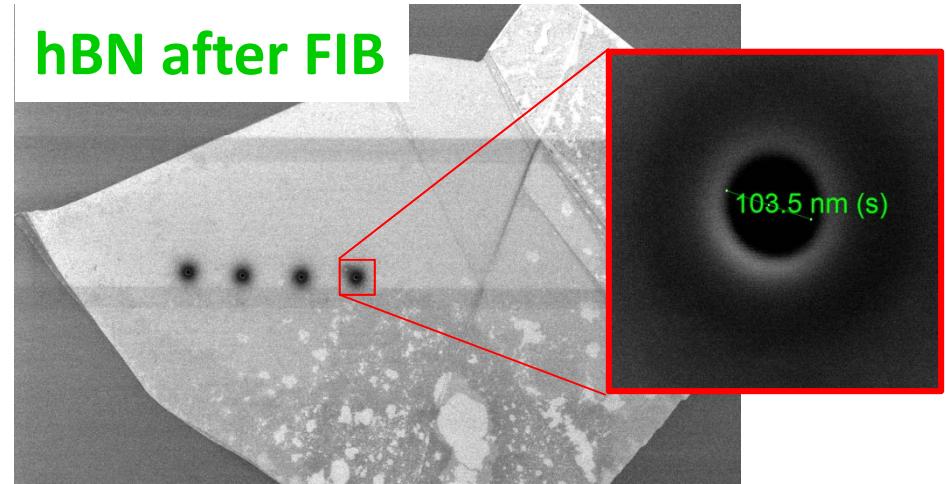
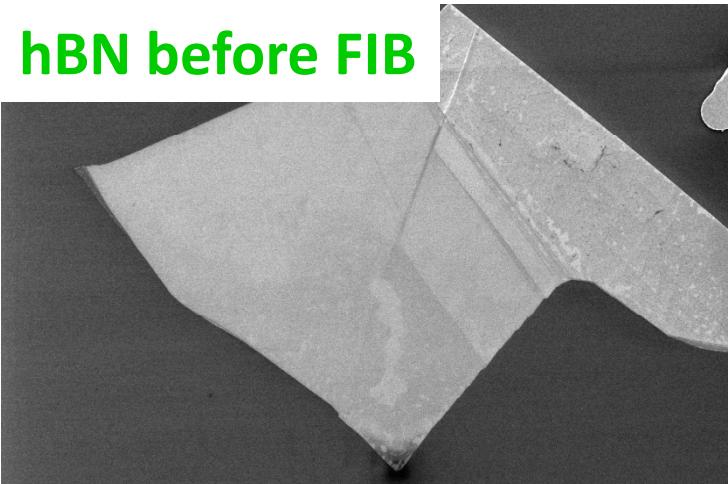


$R_{tip} \approx 100 \text{ nm}$
(chemical etching)

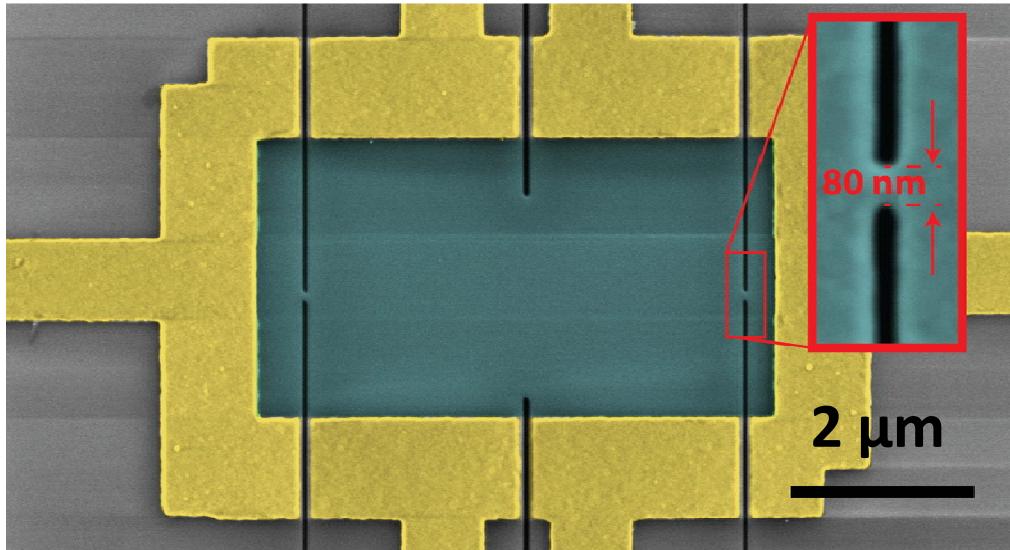


Can be sharpen by FIB milling
 $R_{tip} \approx 20 \text{ nm}$

Inner contact to graphene

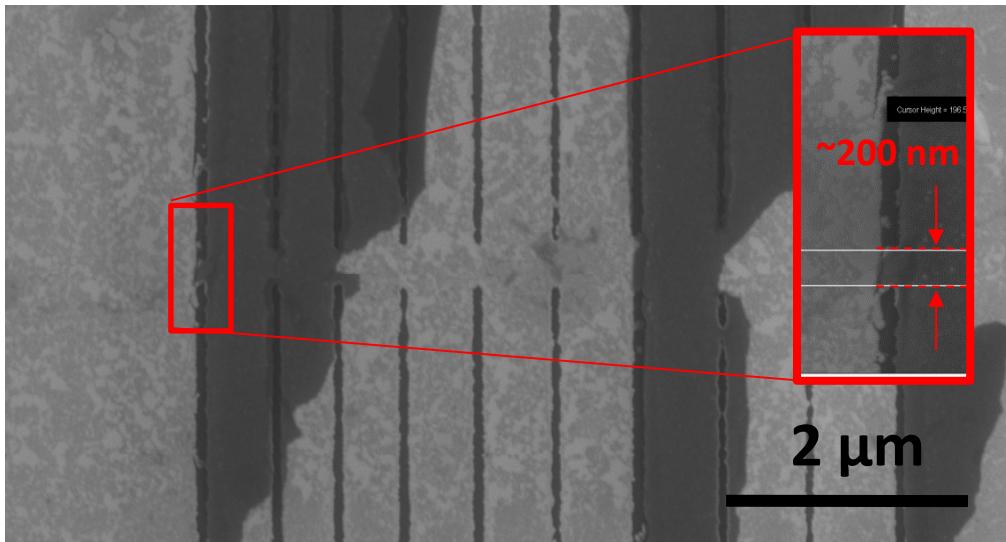


Cuts for SQUIDs



Cut with FIB

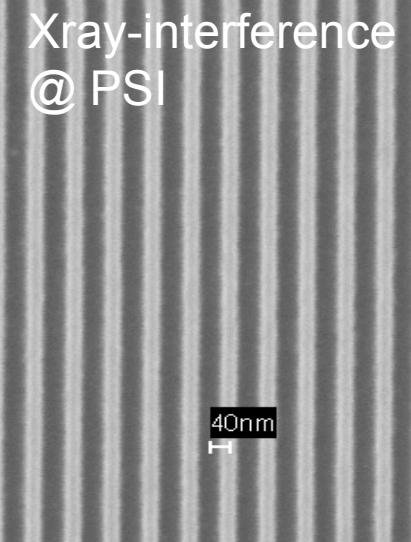
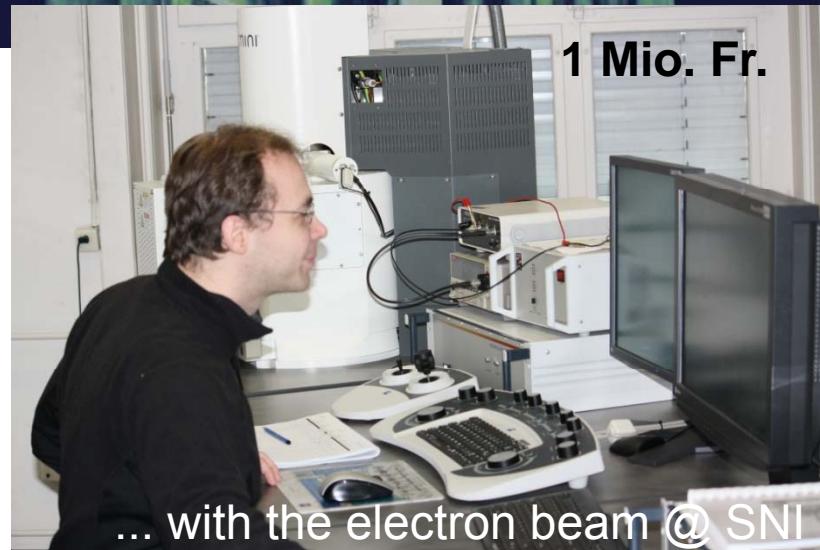
- $d_{\min} \sim 50 \text{ nm}$ possible
- clean cut



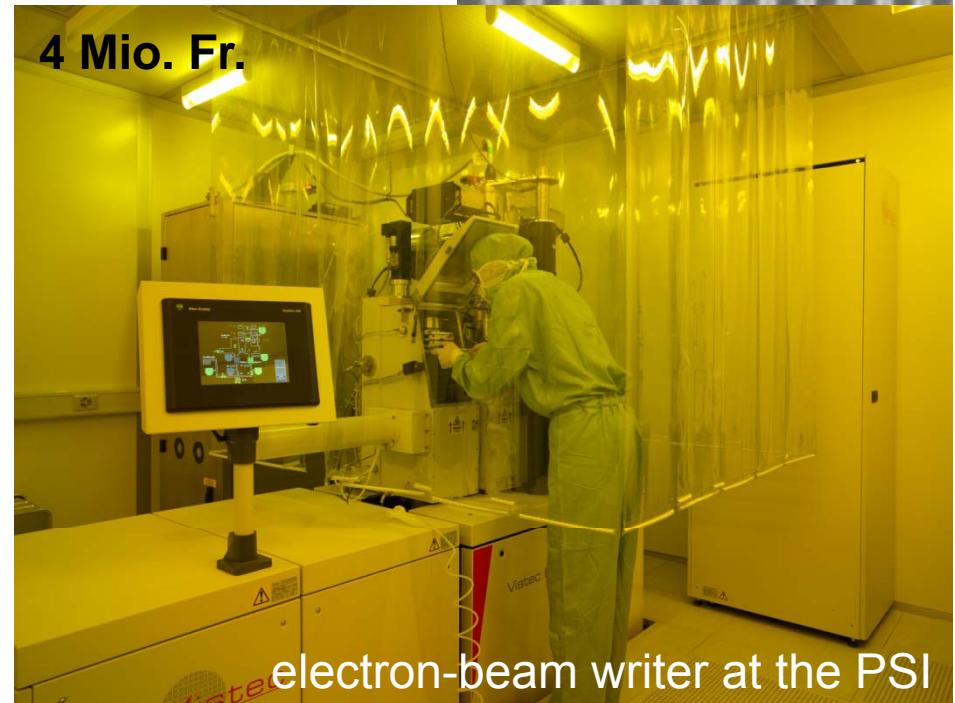
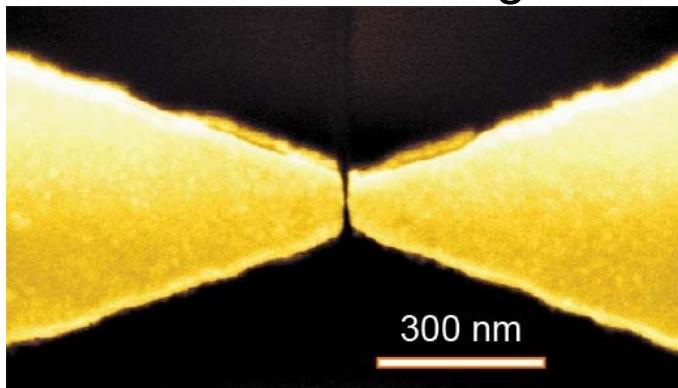
Etched with SF6 (mask with E-beam lithography)

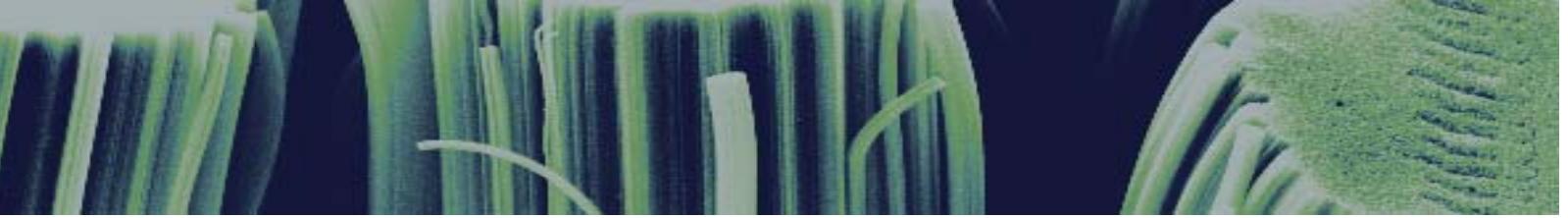
- $d_{\min} \sim 150 \text{ nm}$
- etched cuts are not as clean as with FIB

Key equipment



- light: $1 \mu\text{m}$ down to 10 nm
- e-beam: < 10 nm demonstrated
- focused ion beam: < 10 nm
- He-beam: 2 nm range





SEM-based e-beam writer at SNI/Physics



currently run 2 of those systems (each 1 Mio), but ..

have higher demands:

- a) more groups using it
- b) higher resolution needed (< 10 nm possible)
- c) better overlay accuracy
(10nm stitching possible)
- d) large area patterning
(large field with 24 bit)

Dedicated Electron Beam Lithography



Home » Products » **EBPG5200**

EBPG5200

EBPG5000 Plus

VOYAGER

RAITH150 Two

eLINE Plus

PIONEER

ionLINE

ELPHY MultiBeam

ELPHY Plus

ELPHY Quantum

CHIPSCANNER

Product

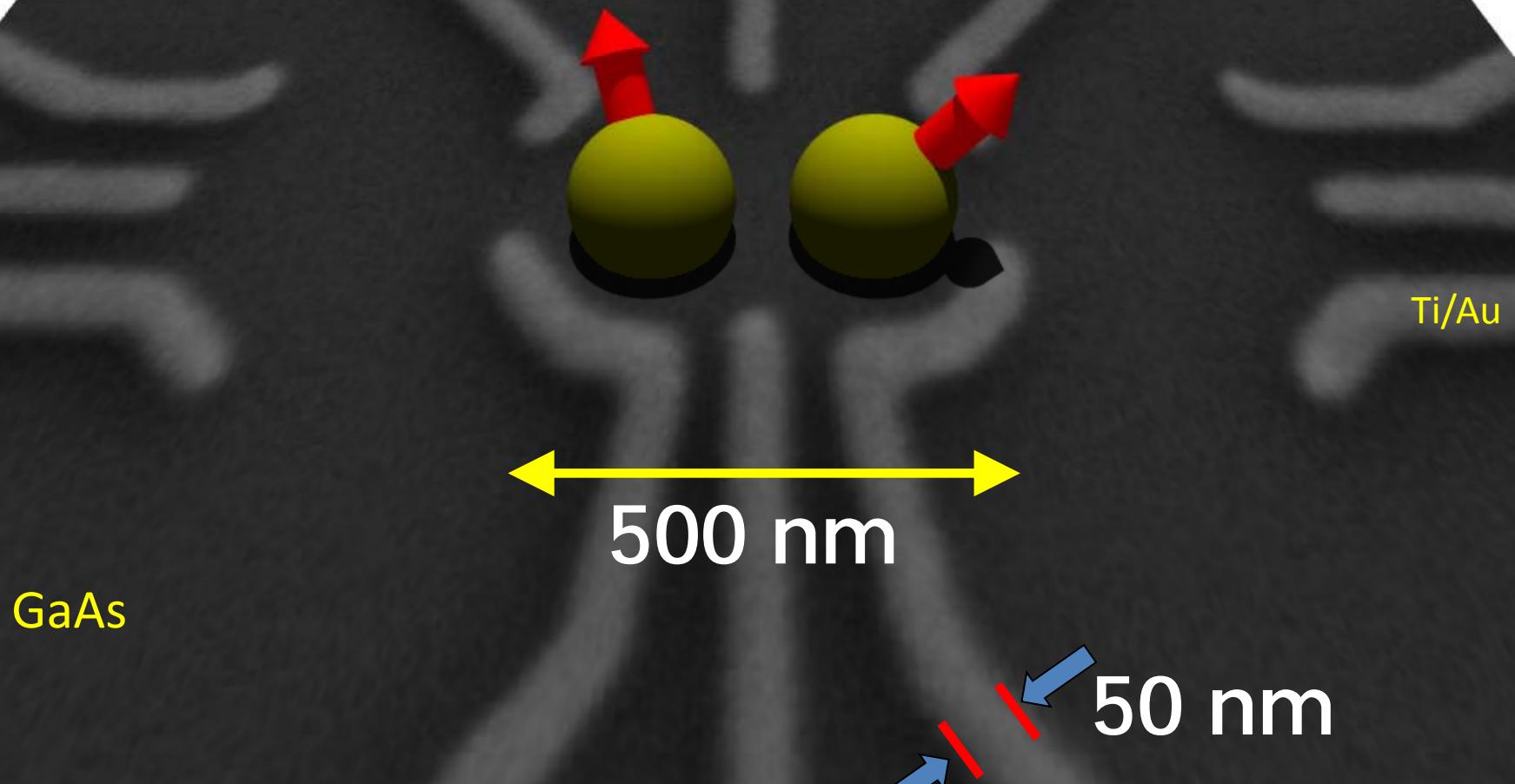
Auto

Evolut

The EBPG5200 is a full 200 nm resolution system providing high speed and field-of-view solutions for making in



Electron Spins in Quantum Dots

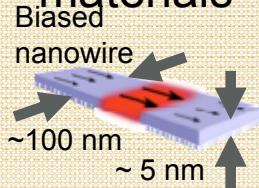


Skalierbarer Quantencomputer
Loss – DiVincenzo (1998)

Superconducting nanowire single-photon detectors (SNSPD)

Warburton and Schönenberger groups (Basel)

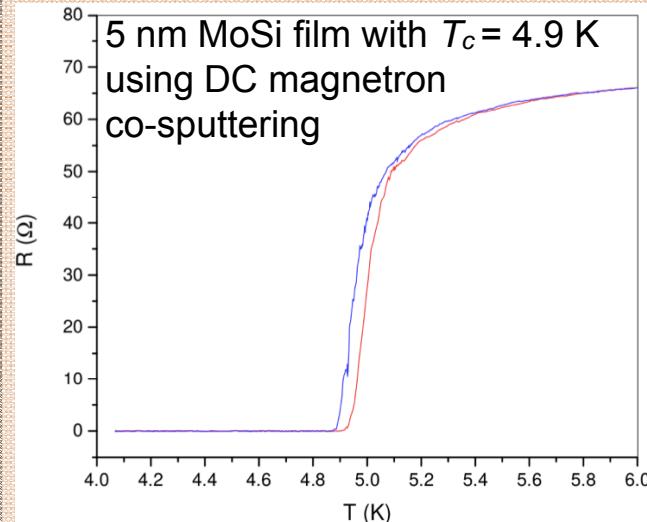
SNSPDs with amorphous materials



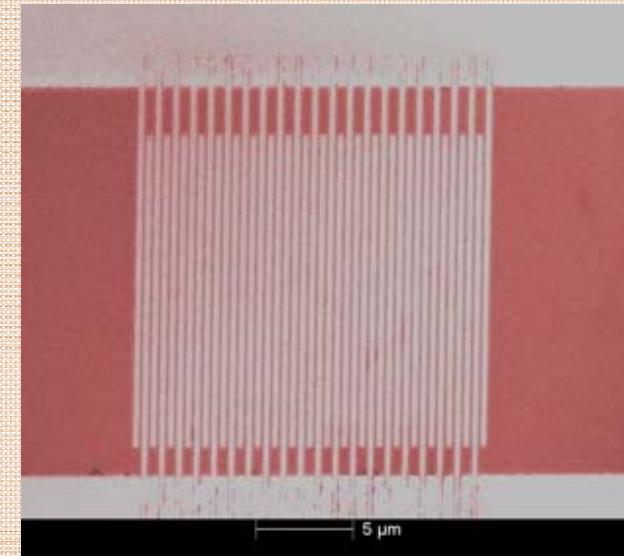
Amorphous material are promising candidates to yield:

- High-efficiency (90%) from visible to telecom
- Low dark count rates (<1 kHz)
- High count rates (< 20 MHz)
- Low jitter (<100 ps)
- Closed-cycle cryo-operation

Thin-film deposition



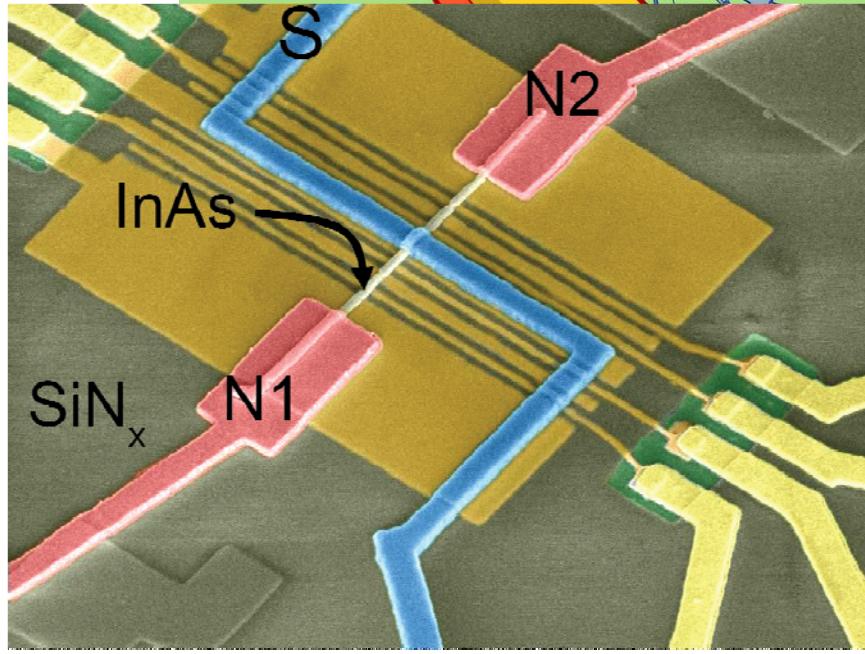
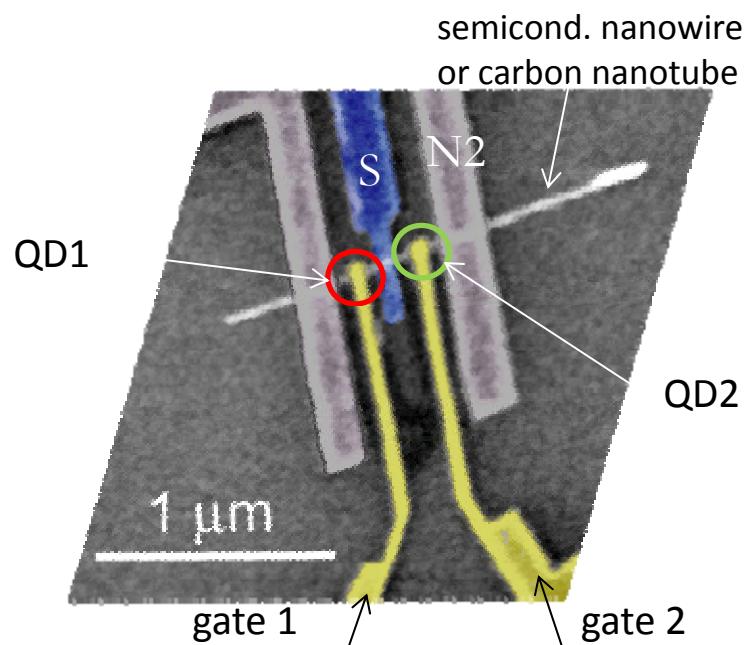
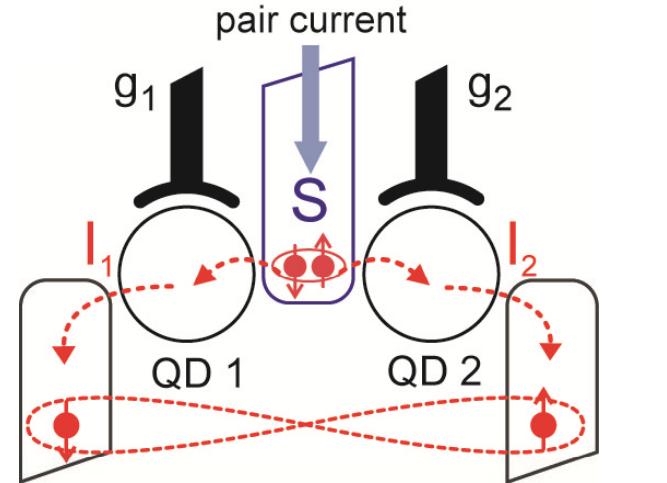
Nano-fabrication



- e-beam lithography for top-down nanowire fabrication

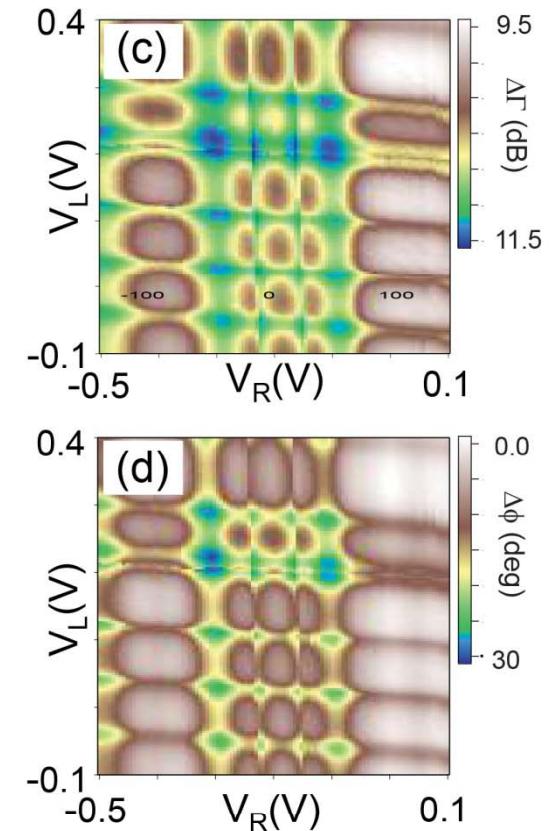
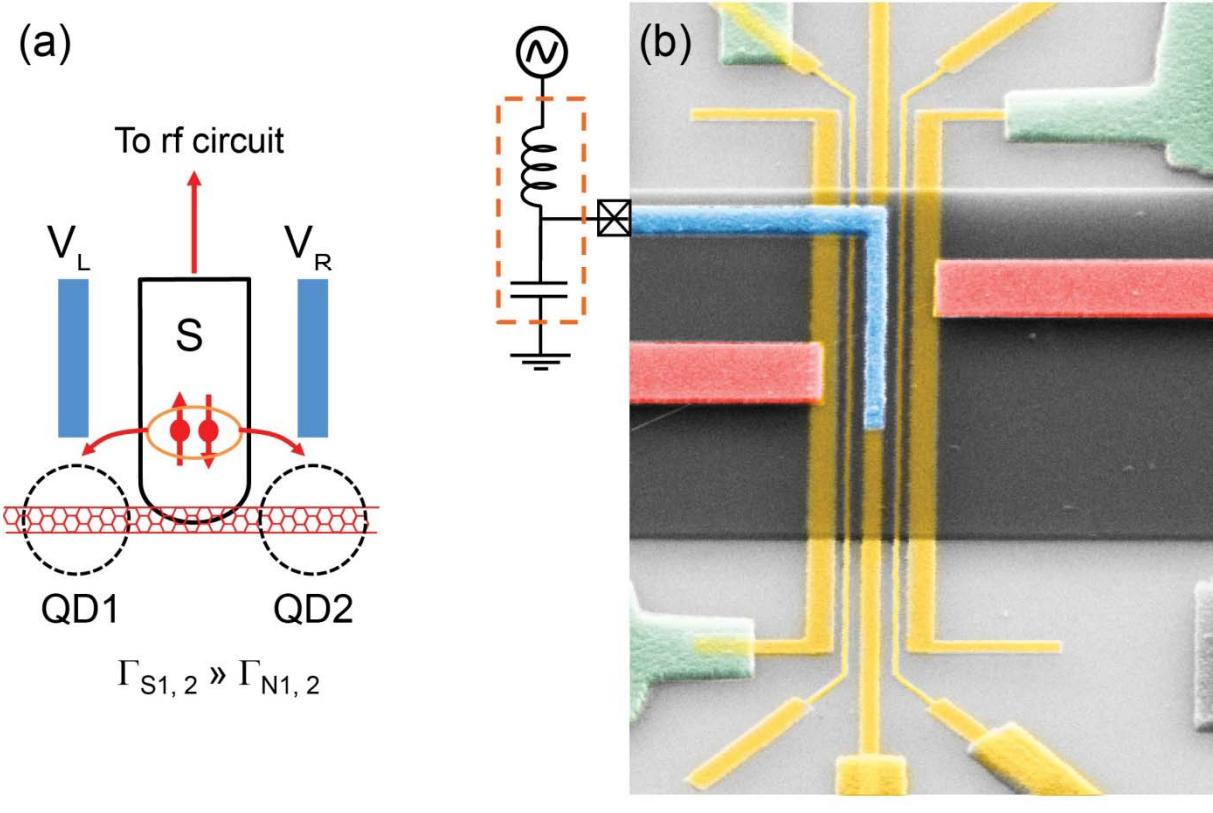
Cooper-pair splitter

apply quantum dots to split Cooper-pairs;
proposal by Recher, Sukhorukov and Loss



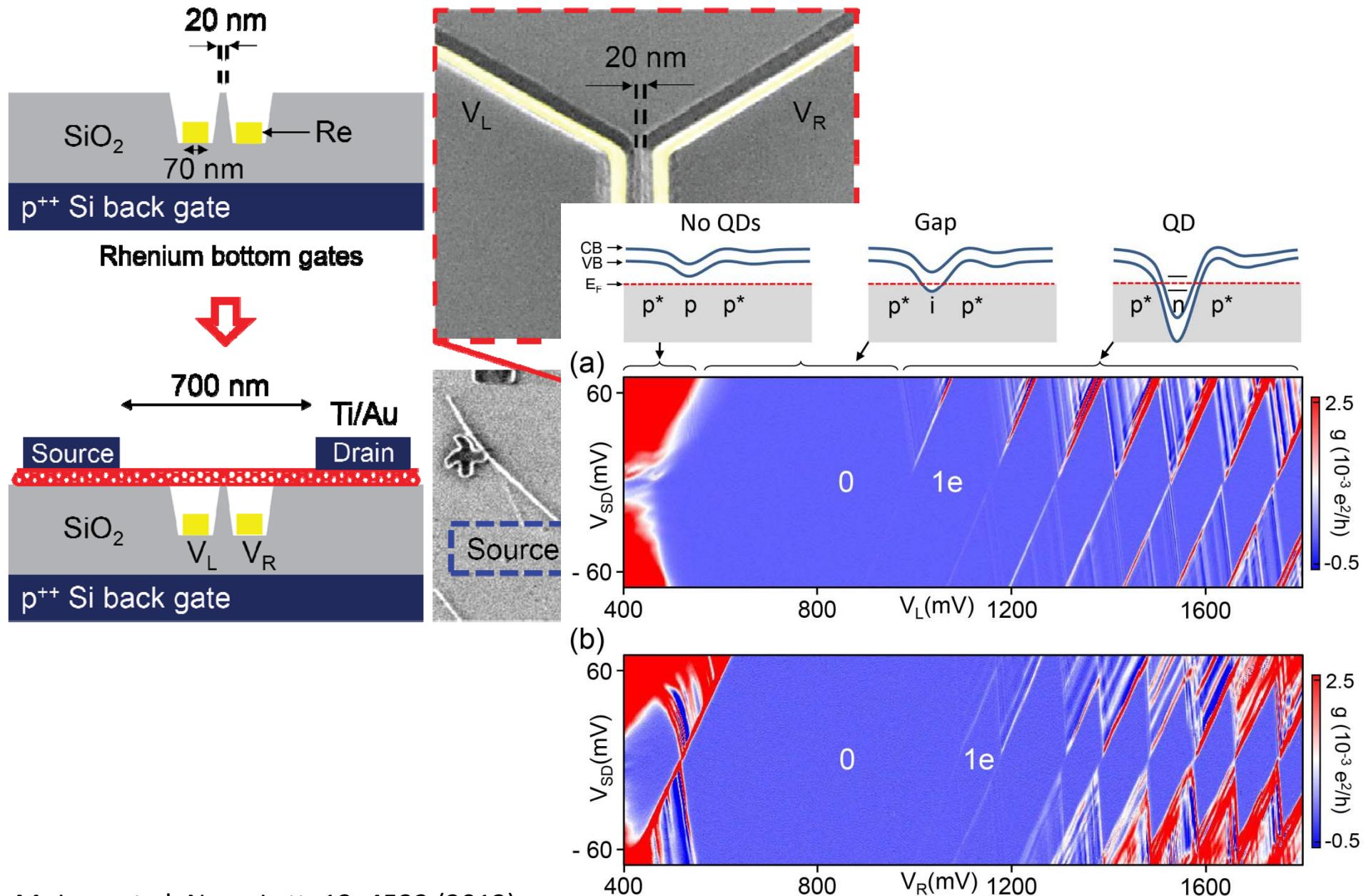
Hofstetter et al. Nature 461, 960-963 (2009)

Cooper-pair splitter

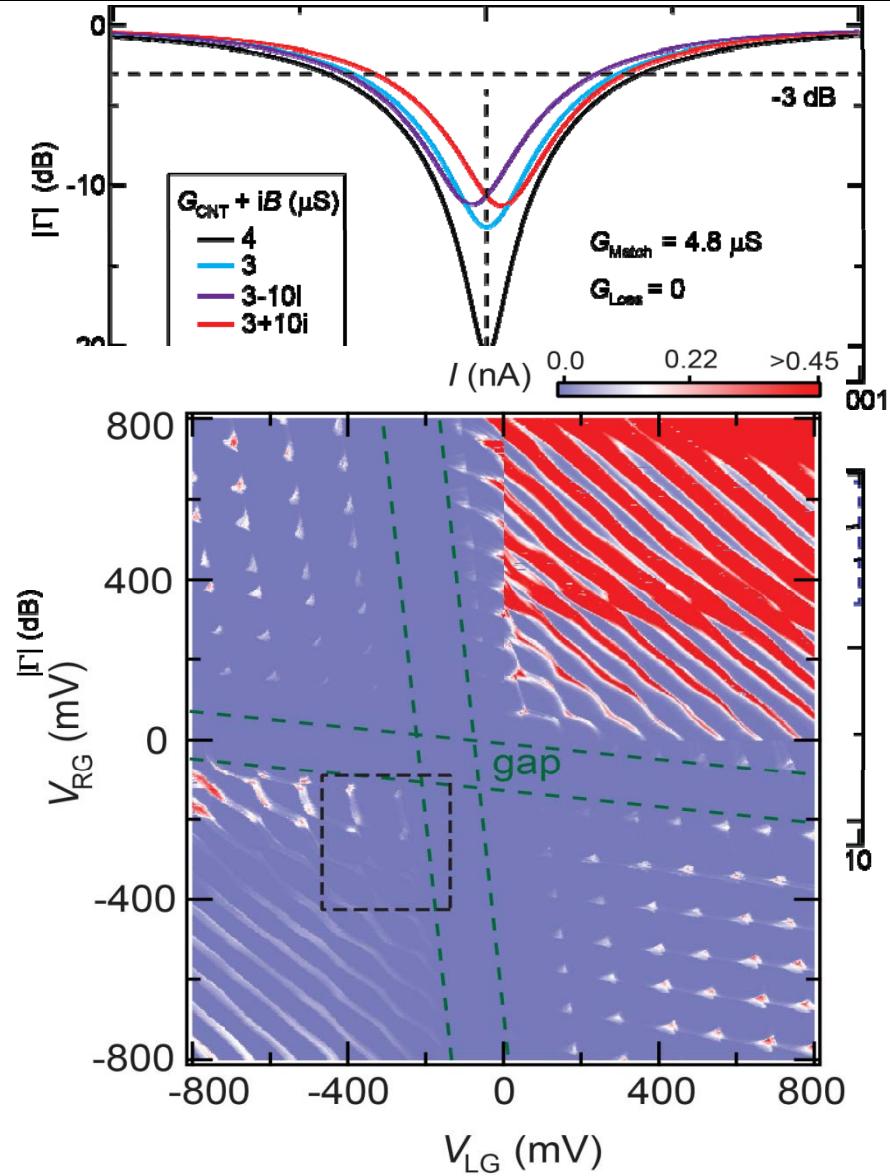
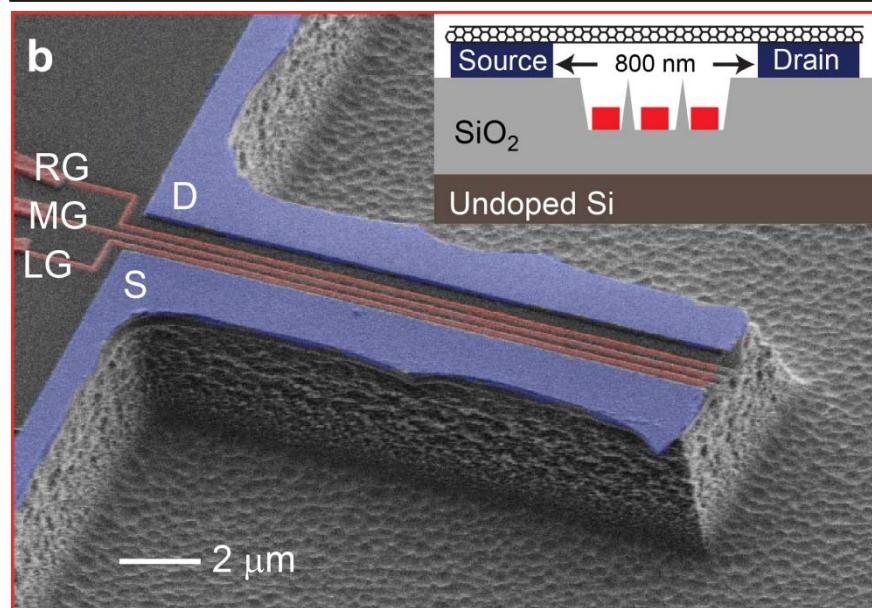
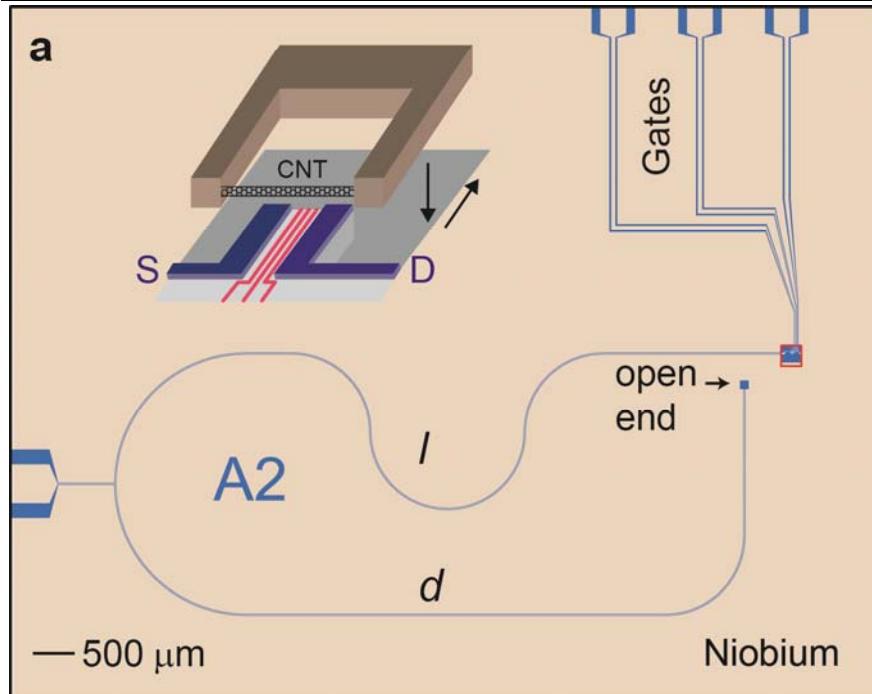


modern one with a single CNT and coupled to an rf circuit
work in progress

Carbon Nanotube (CNT) Quantum Dots (qdots)

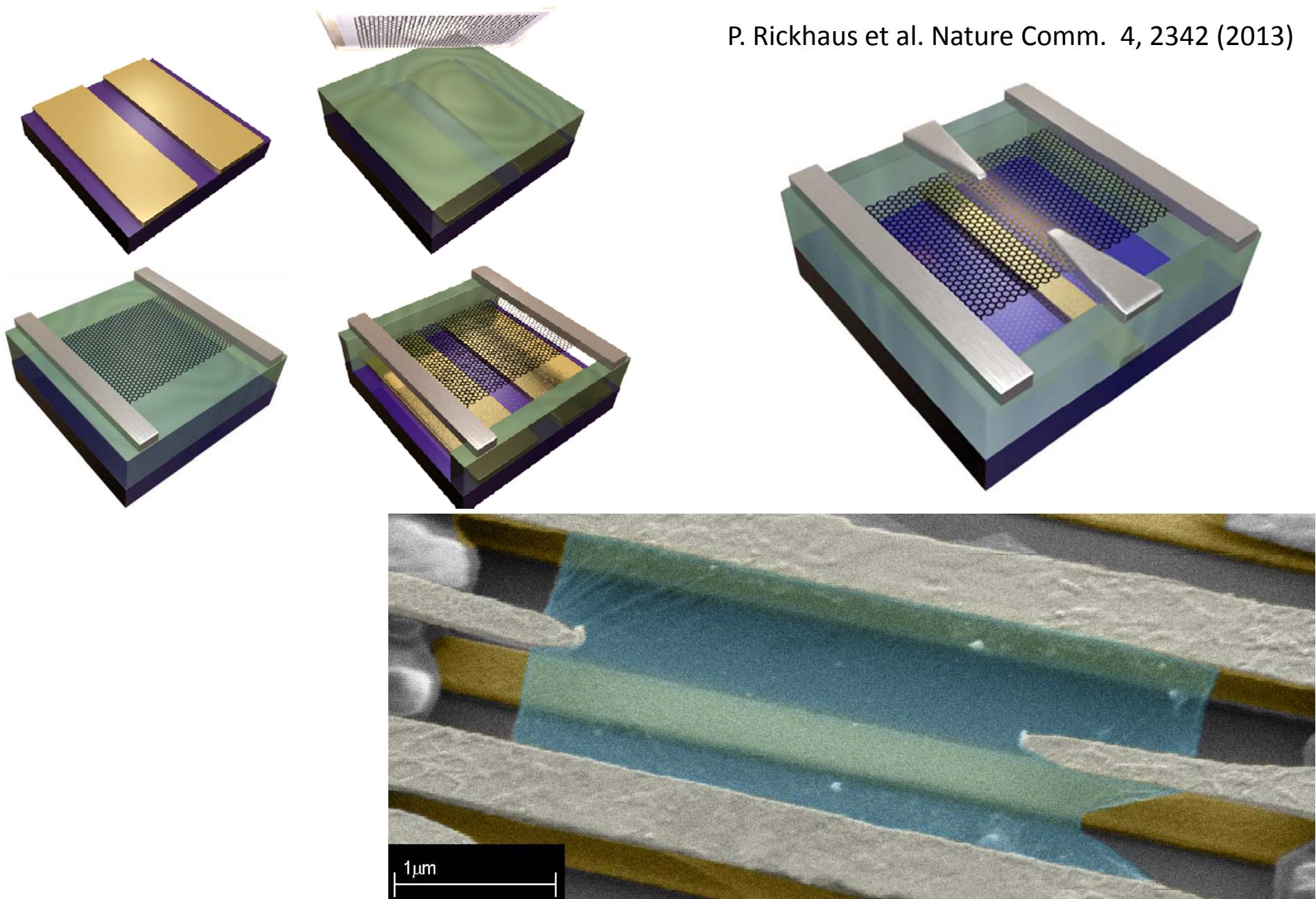


CNT Qdots coupled to rf cavities

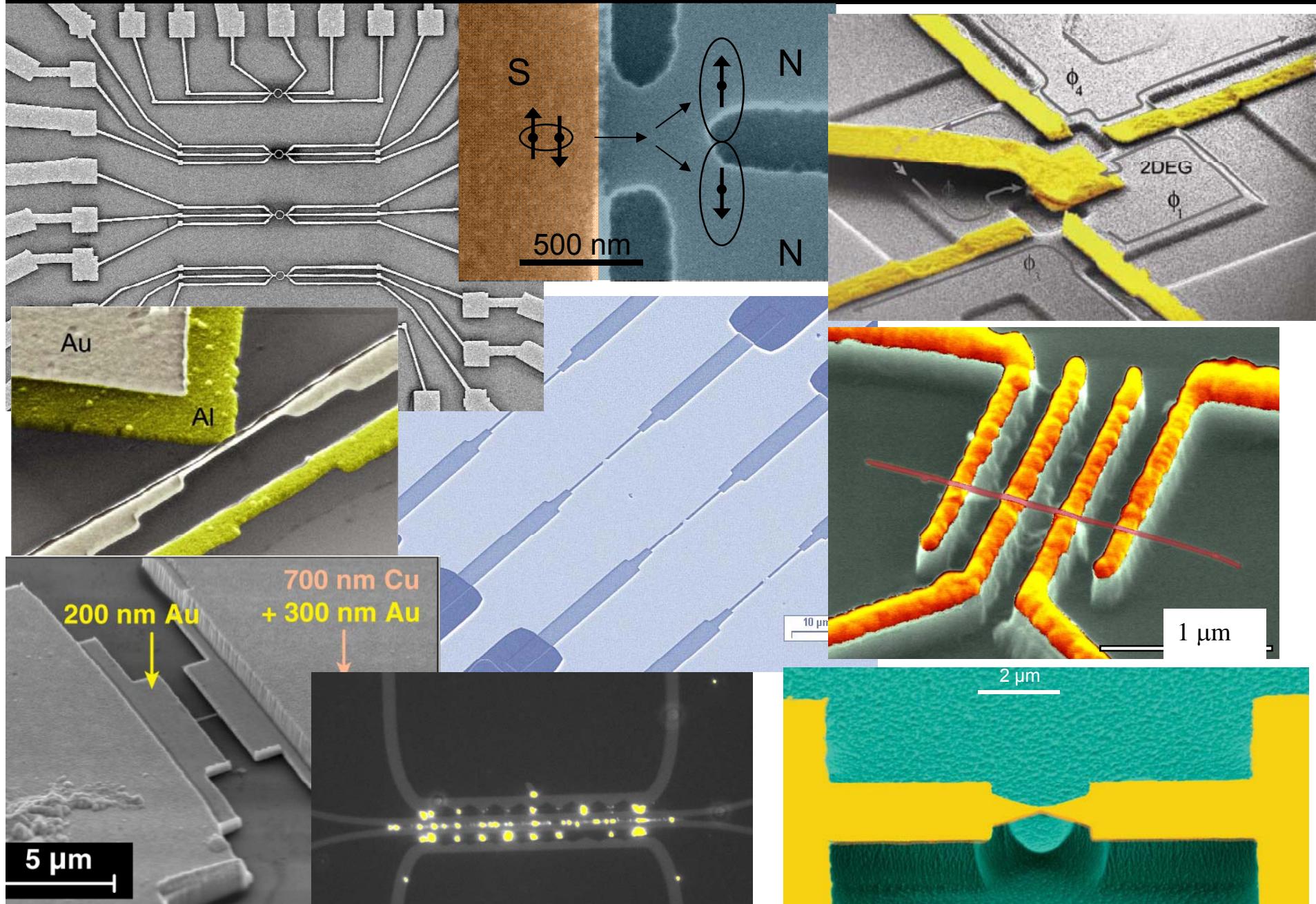


Graphene devices (suspended)

P. Rickhaus et al. Nature Comm. 4, 2342 (2013)



some more pics of devices



2. Quantum Primer

2. Quantum Primer

a) Wave-Mechanics („like“ optics, acoustics ...)

(energy $E=const$)

Schrödinger

$$\left\{ \Delta + 2m(E - V)/\hbar^2 \right\} \psi = 0$$

Helmholz

$$\left\{ \Delta + (E/c\hbar)^2 \right\} \psi = 0$$

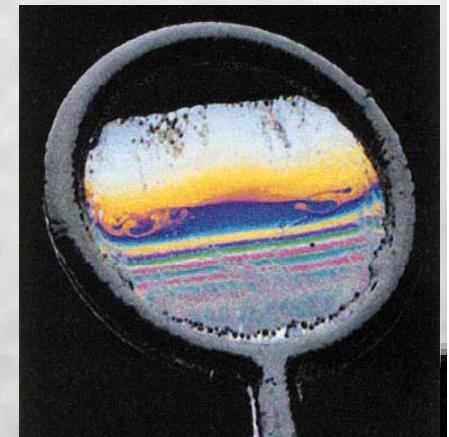
waves:

$$\psi = A \exp(iS/\hbar)$$

A : Amplitude

$\Theta = S/\hbar$ Phase (determined by the action S)

(the whole classical physics
is contained in the phase)



2. Quantum Primer

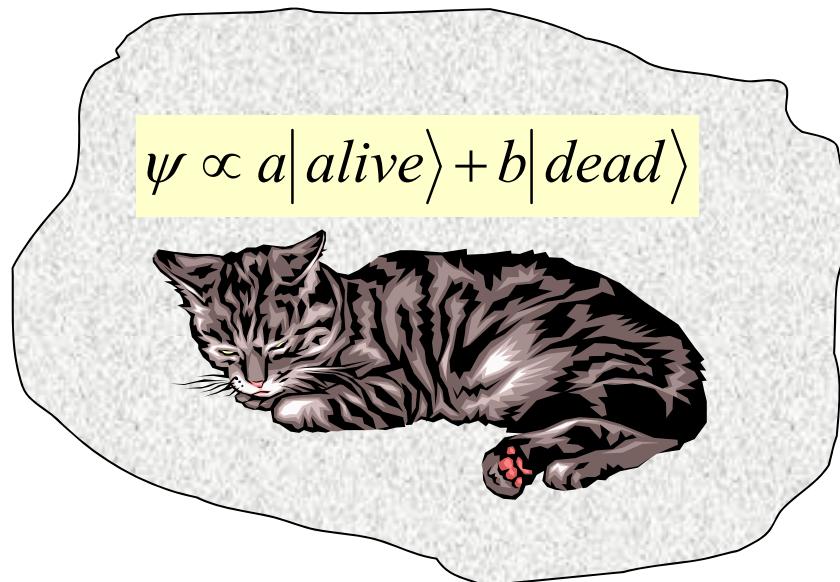
b) add some weirdness

uncertainty relations: $[x, p] = i\hbar$

(not quite weird, formally a consequence of Fourier transformation)

c) some more weirdness

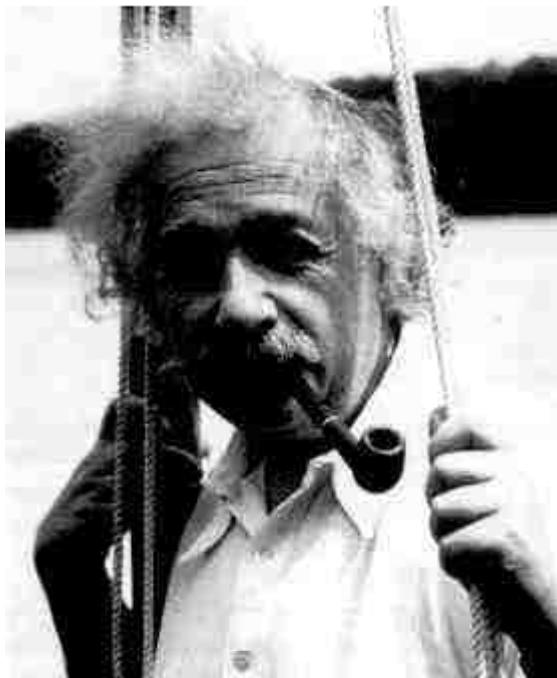
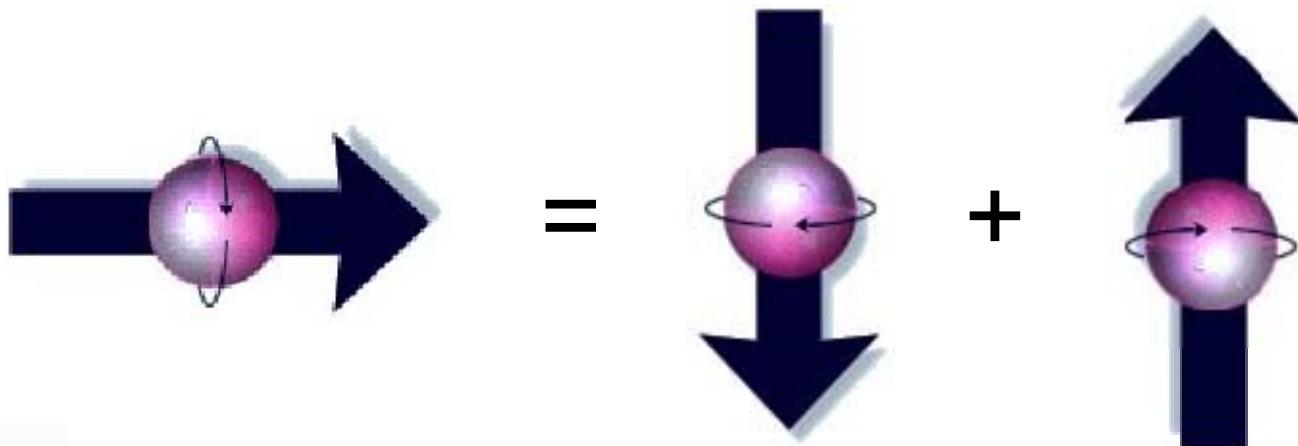
Copenhagen interpretation of Ψ „collapse of wavefunction“



- linear superposition
- **cat is both dead and alive**
- only if **measured** is the cat **either dead or alive!**

2. Quantum Primer

superposition



many measurements:

50% point up
50% point down

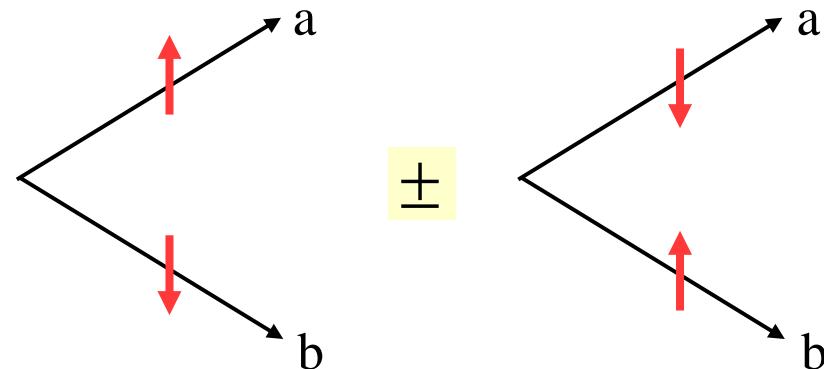
quantum physics is therefore
probabilistic and not deterministic

„Gott würfelt nicht!“

2. Quantum Primer

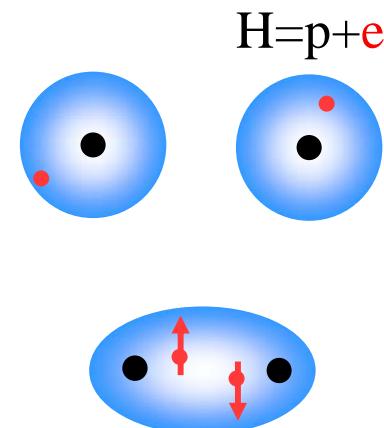
d) higher level weirdness

many-particle states, **entangled states!**

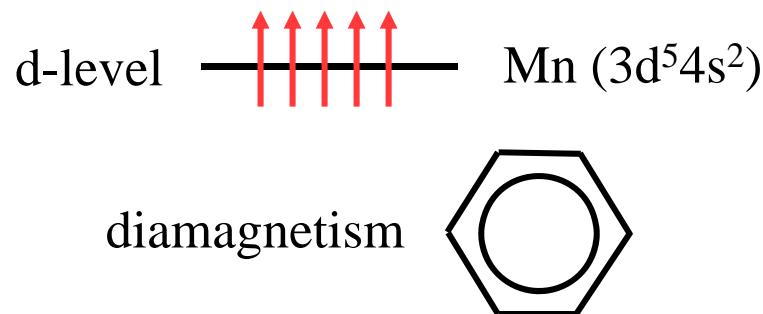


$$|a \uparrow\rangle|b \downarrow\rangle \pm |a \downarrow\rangle|b \uparrow\rangle$$

Chemistry



Magnetism



- we all live on quantum mechanics
- we would **not exists without** QM!
- a classical world is unstable!

3. Conceptual discussions (blackboard)

- quantities yielding different energies, T, B, f, L ...
- ballistic vs diffusive
- quantum coherence
- energy conserving vs relaxation (damping)
- what is classical, which classical concepts break down
- quantum transport “*phenomenology*”

3. Conceptual discussions (blackboard)

<i>Limit</i>	<i>Length</i>	<i>Conserved quantity</i>
Ballistic	$L \ll \ell_{\text{el}}, \ell_{\text{e-e}}, \ell_{\text{e-ph}}$	current for each momentum state
	↓ elastic scattering: randomizes momentum direction	
Diffusive, non-equilibrium	$\ell_{\text{el}} \ll L \ll \ell_{\text{e-e}}, \ell_{\text{e-ph}}$	current for each energy
	↓ electron-electron scattering: mixes different energies	
Quasi-equilibrium	$\ell_{\text{el}}, \ell_{\text{e-e}} \ll L \ll \ell_{\text{e-ph}}$	charge and energy currents
	↓ electron-phonon scattering: energy exchange with environment	
Local equilibrium	$\ell_{\text{el}}, \ell_{\text{e-e}}, \ell_{\text{e-ph}} \ll L$	charge current

Table 2.1 Different limits for the distribution function, defined by comparing the size L of the wire to the scattering lengths.

4. Phenomena in quantum transport

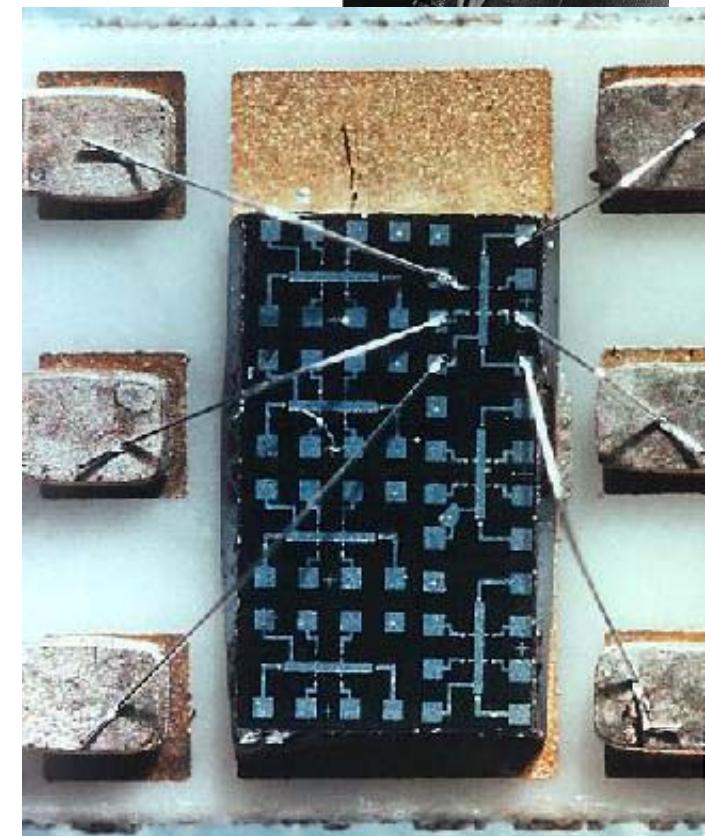
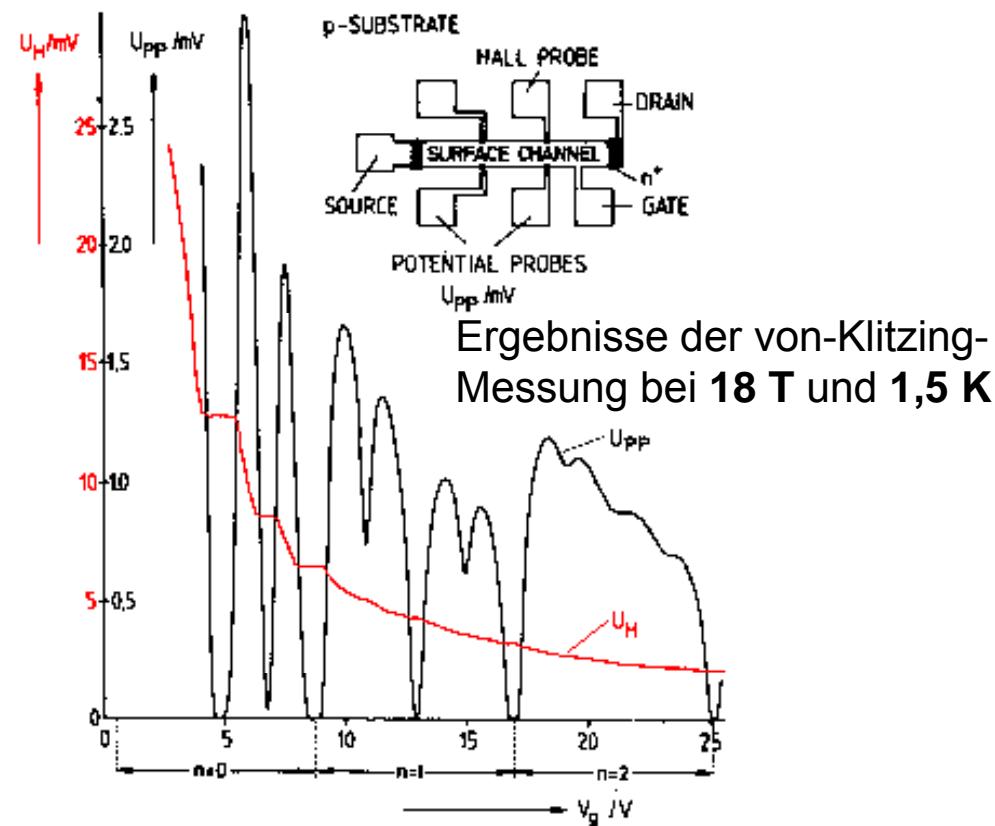
4.1 Quantum Hall Effect

1980 discovered by K. von Klaus von Klitzing in Grenoble

Untersuchung der Hall-Spannung von MOS-FET bei tiefen Temperaturen und starken B-Feldern

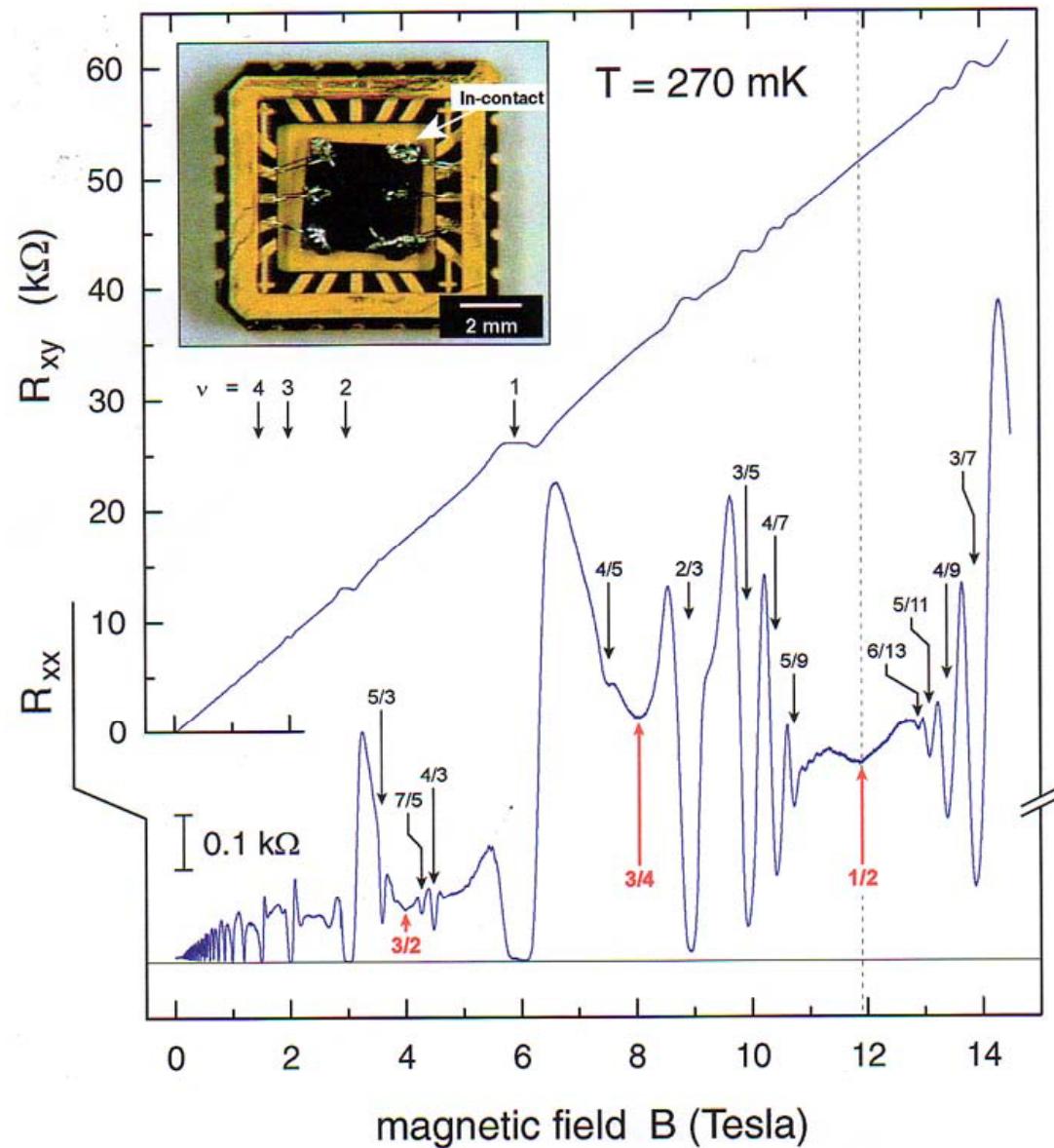
Deutung: **Quantisierung** des Hall-Widerstands

1985 Nobelpreis für Physik

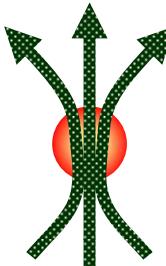


Originalprobe. Deutschen Museum Bonn

4.1 Quantum Hall Effect



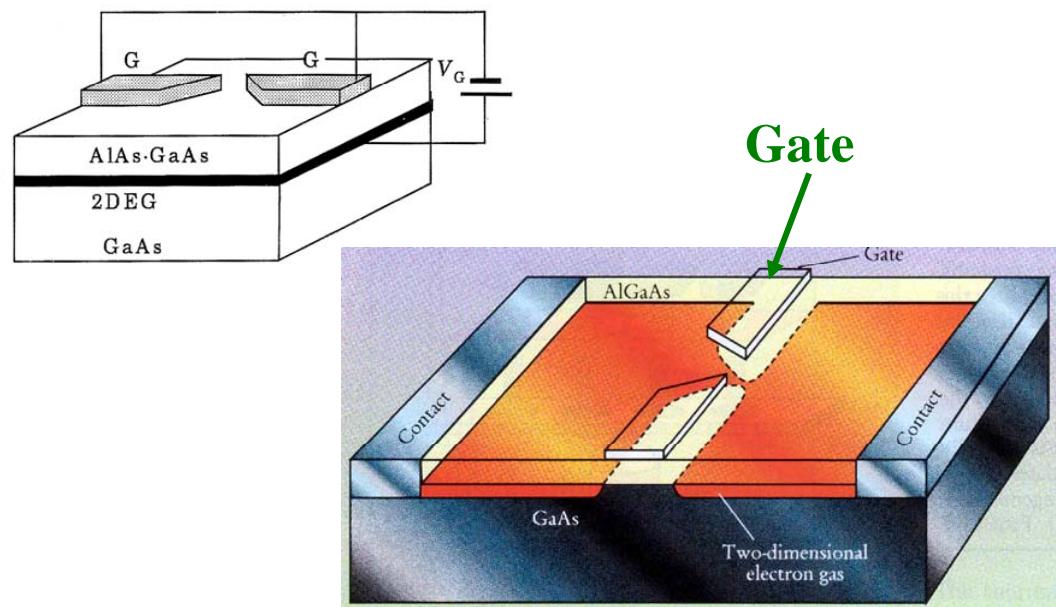
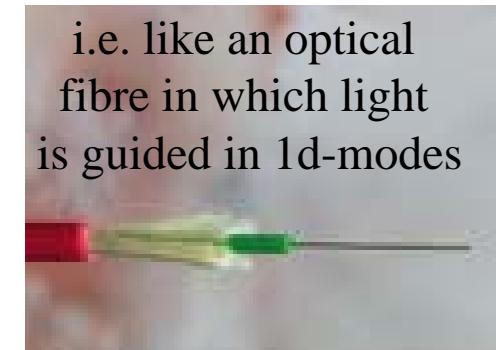
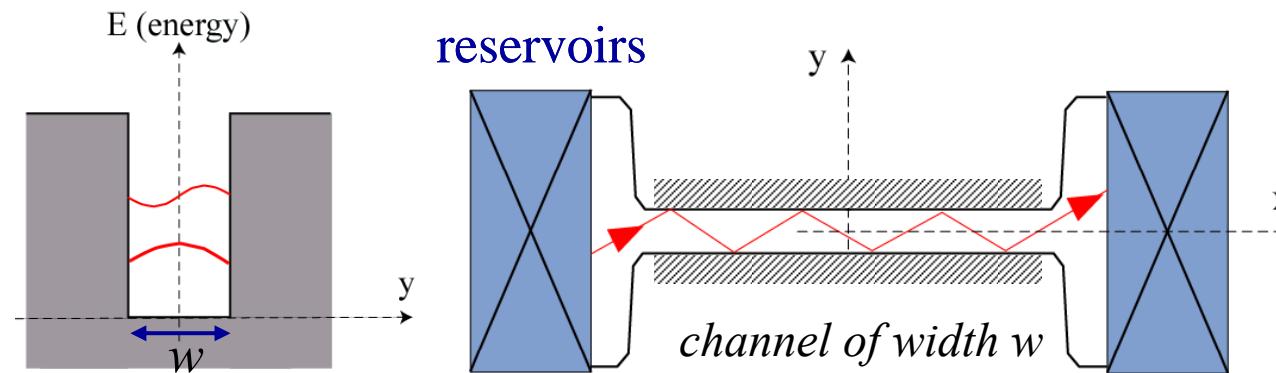
e.g. at filling $1/3$



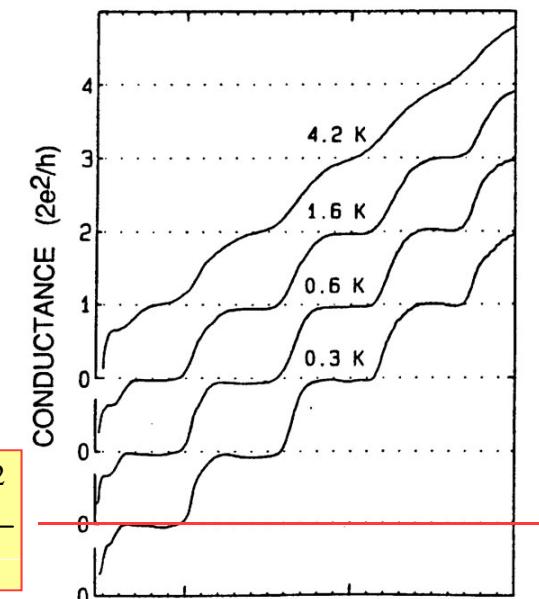
composite particle:
 $1 \text{ e} + 3 \Phi_0$

excitations (quasiparticles)
have **fractional charge**
(observed in experiment)

4.2 Quantum wire



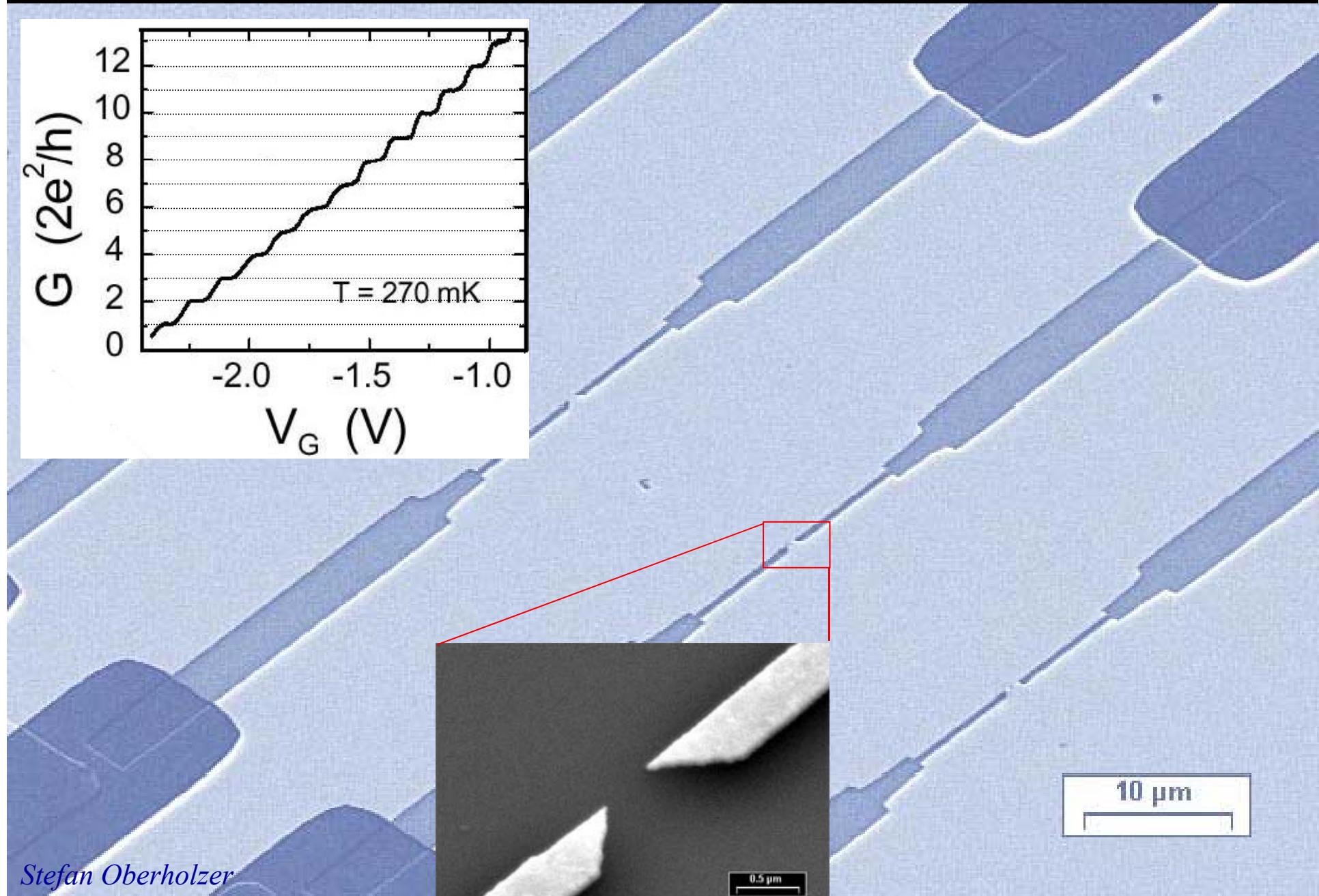
$$G_0 = \frac{2e^2}{h}$$



Gate Voltage \propto width w

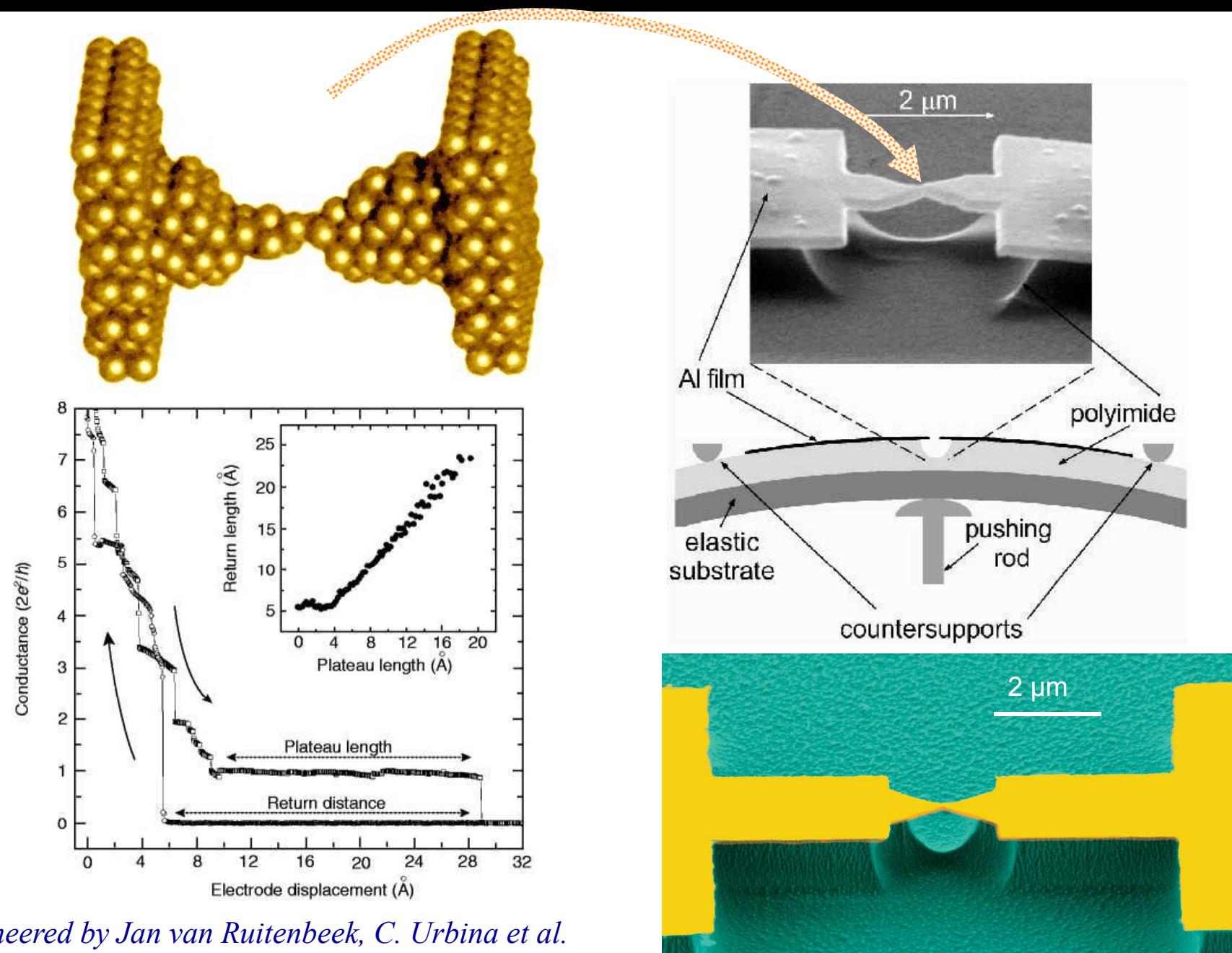
van Wees, van Houten 1988

4.2 Quantum (wire) point contact (QPC)



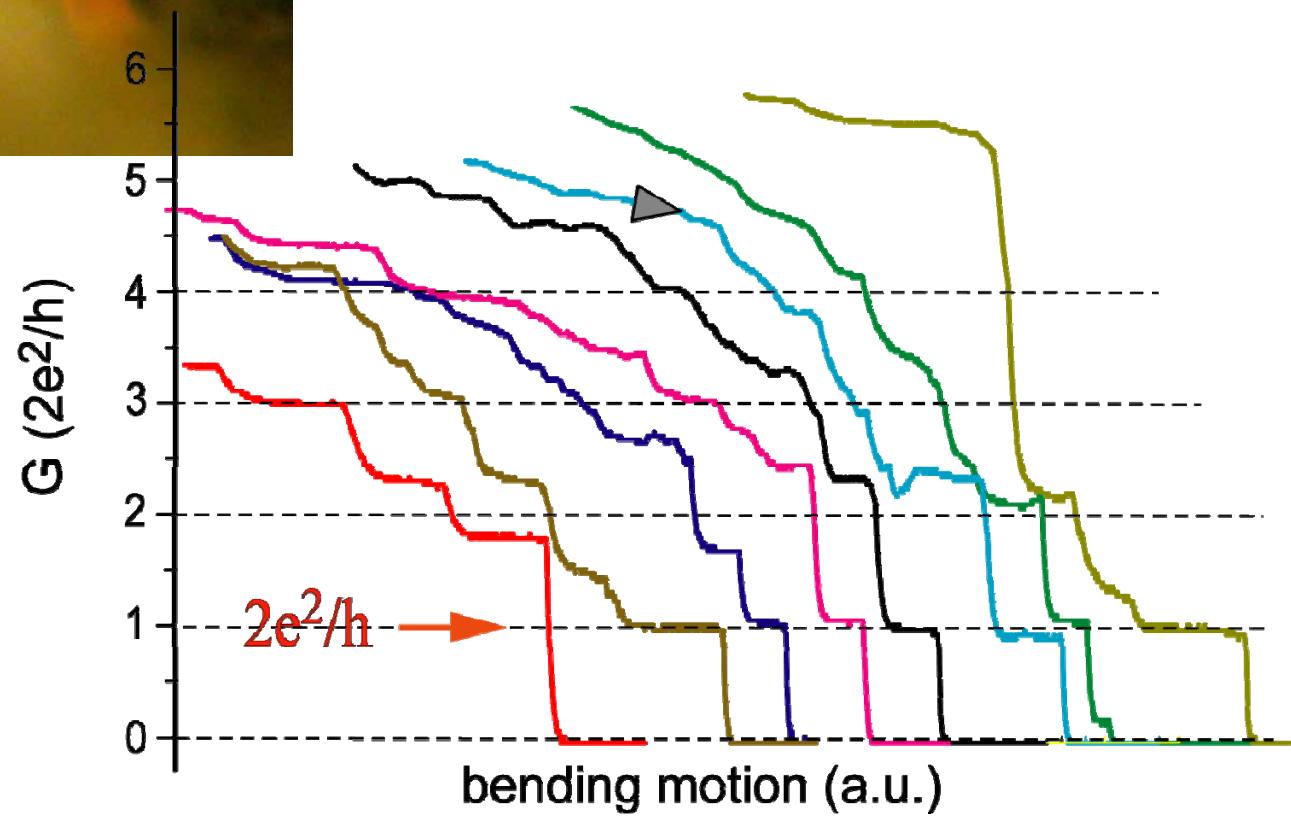
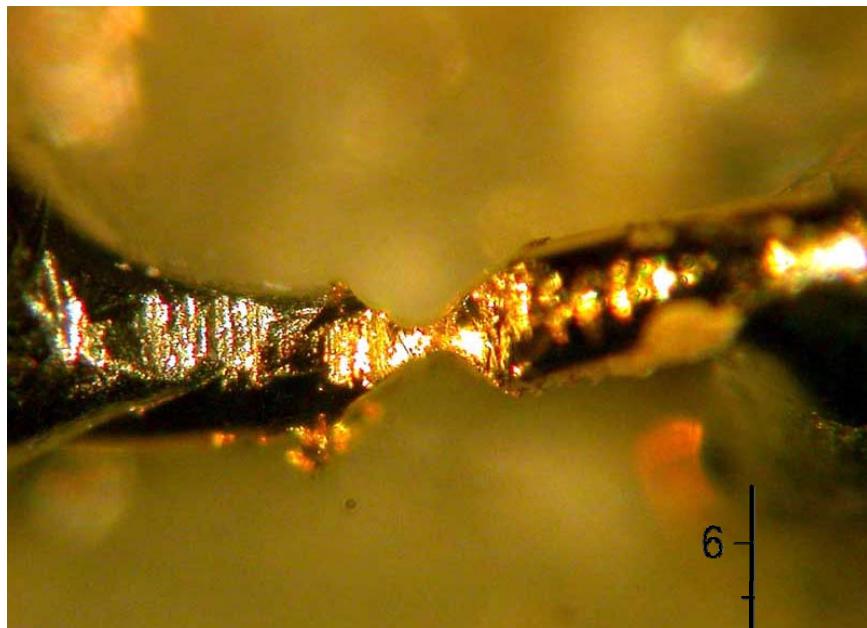
Stefan Oberholzer

4.2 Quantum point contact (QPC)



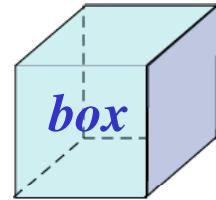
pioneered by Jan van Ruitenbeek, C. Urbina et al.

4.2 Quantum point contact (QPC)



4.3 Quantized charge and flux

Millikan 1911
isolated piece of matter



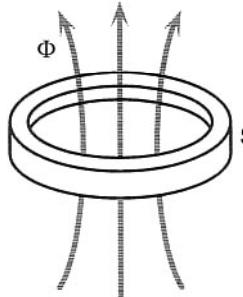
charge Q is quantized

$$Q = ne$$

(capacitor C)

superconducting ring

dual

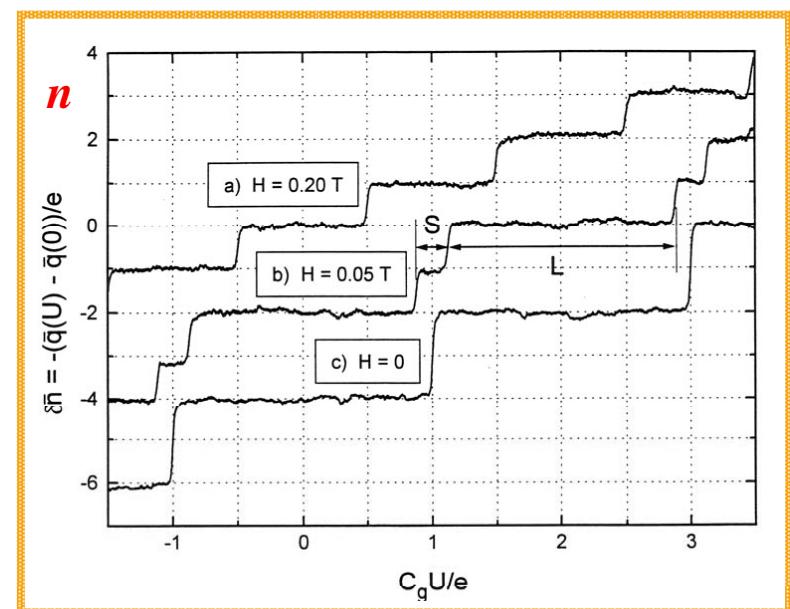


flux Φ is quantized

$$\Phi = n(h/2e)$$

(inductor L)

solid-state version of
Millikan's oil droplet experiment

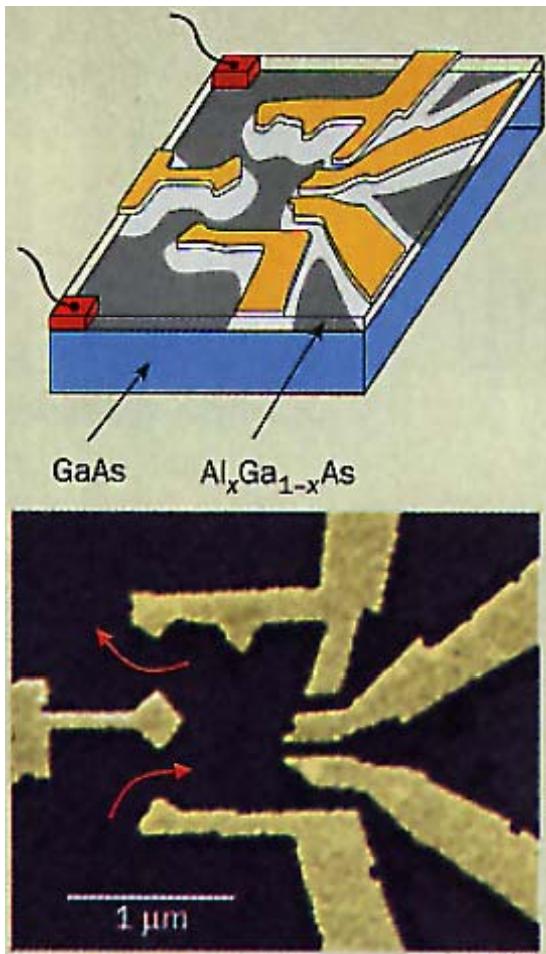


(Lafarge, Pothier, Bouchiat, Esteve, Devoret)

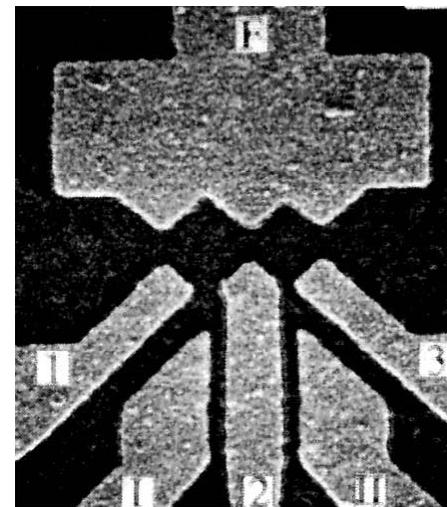
4.4 Quantum dots

“small” cavities

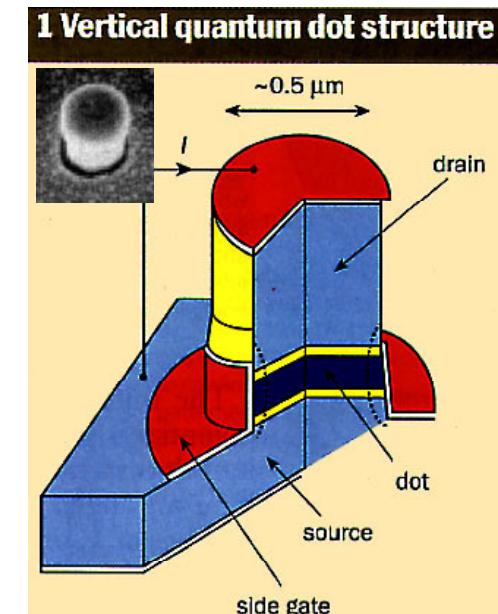
planar dot



planar double-dot



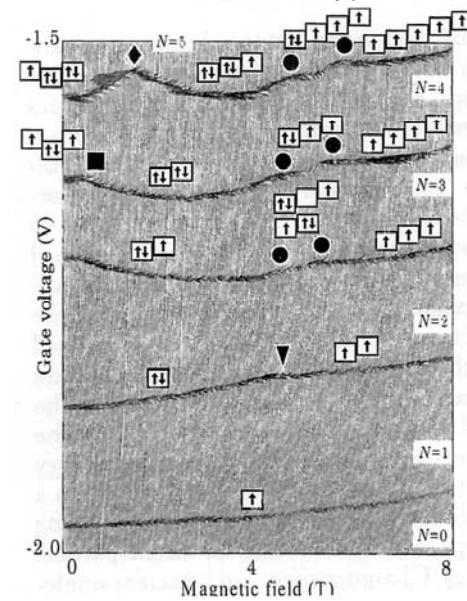
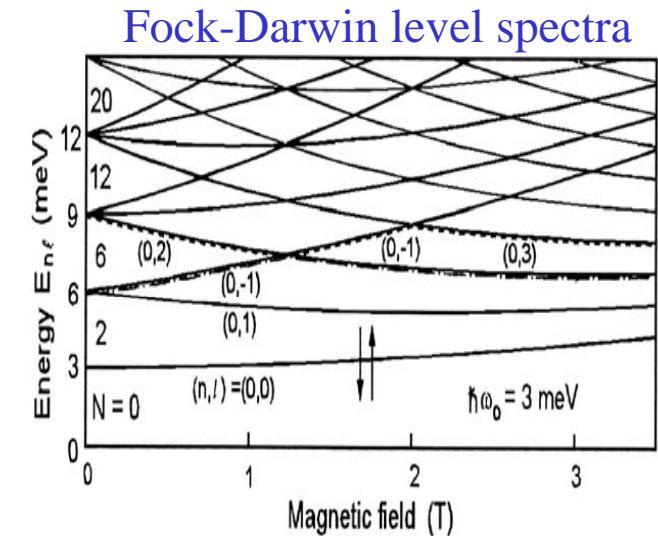
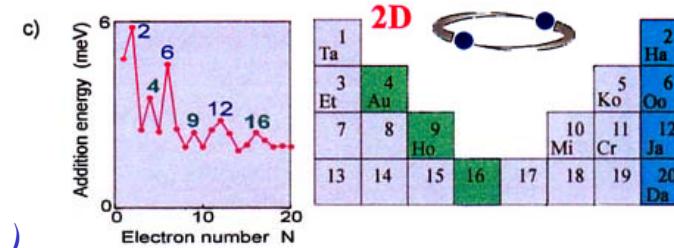
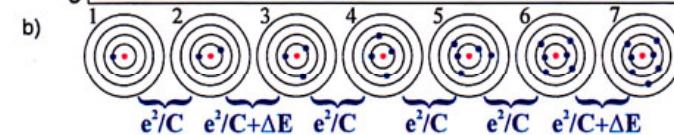
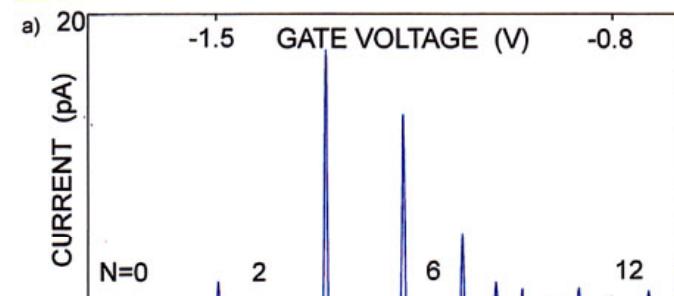
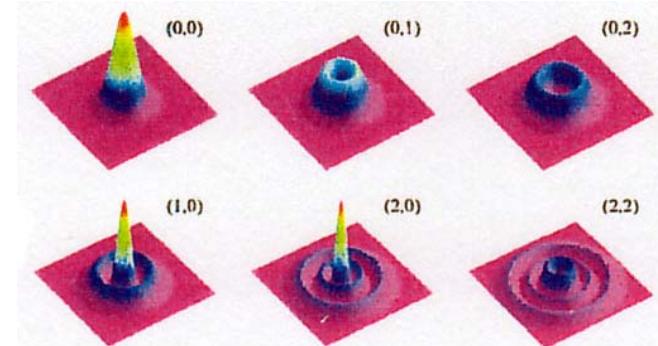
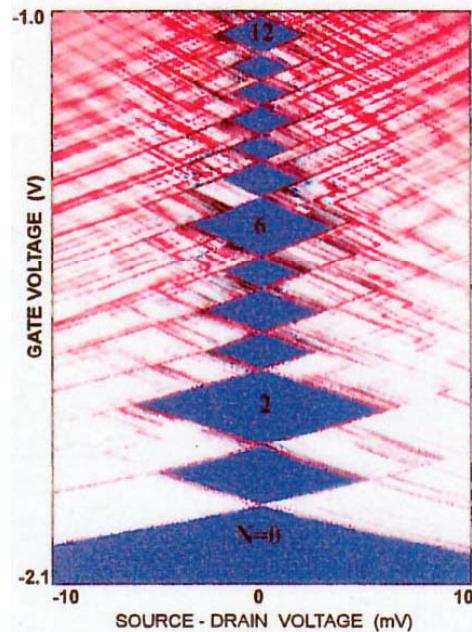
vertical dot



... planar multi-dot

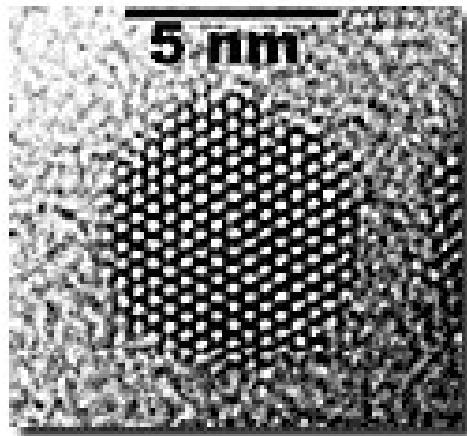
4.4 Quantum dots

few electron quantum dots



(Kouwenhoven, Tarucha et al.)

4.4 Quantum dots



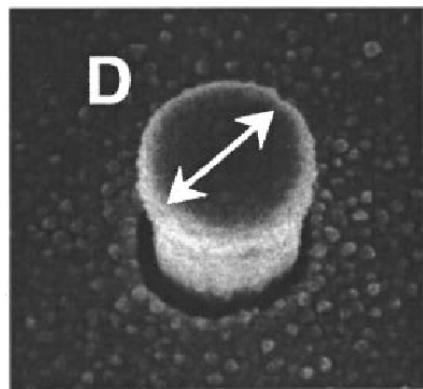
TEM by Andreas Kada vanich.
Transmission electron microscopy shows the crystalline
arrangement of atoms in a
5 nm CdSe Qdot particle.



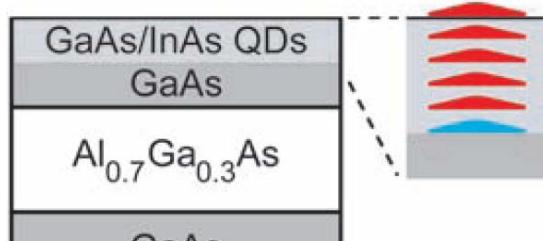
A family of Qdot particles can be made to emit
a full spectrum of colors when excited with a
single excitation source.



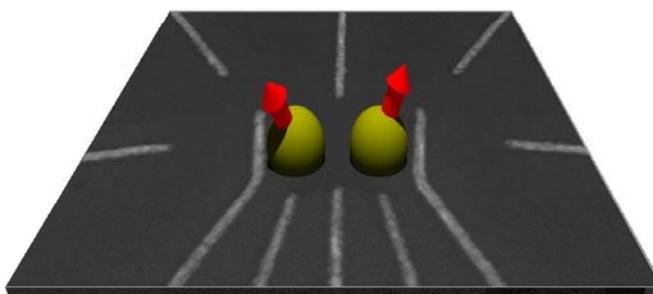
4.4 Quantum dots



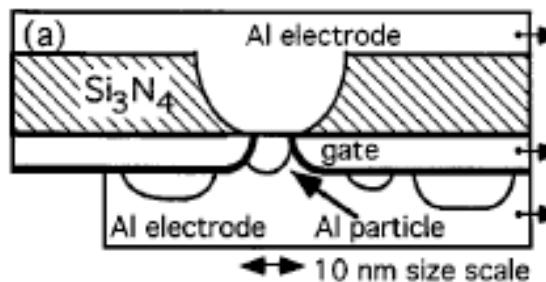
GaAs vertical



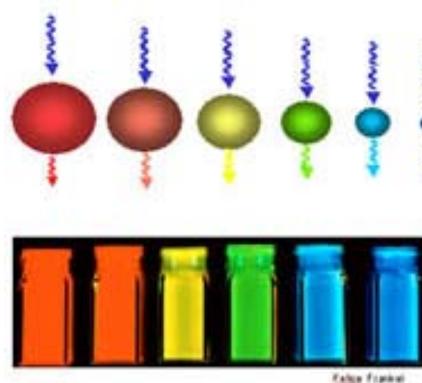
MBE grown



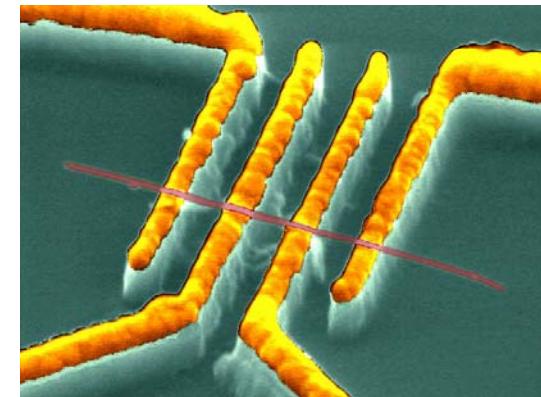
GaAs lateral



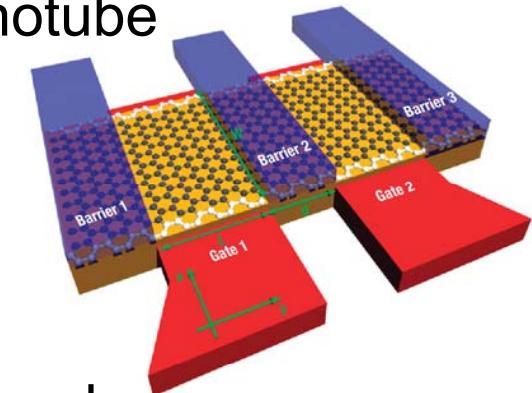
metal grain



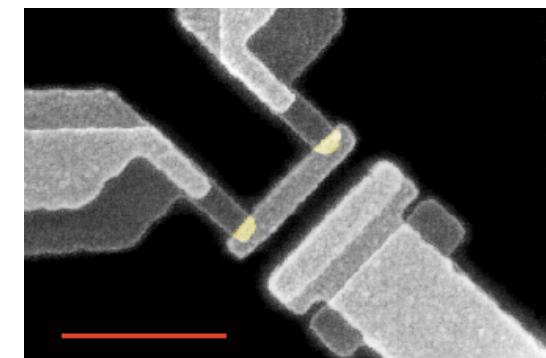
self assembled



nanotube

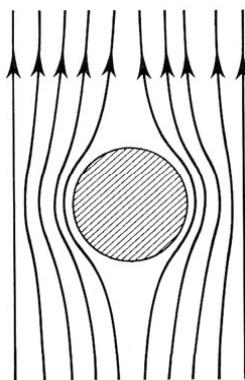
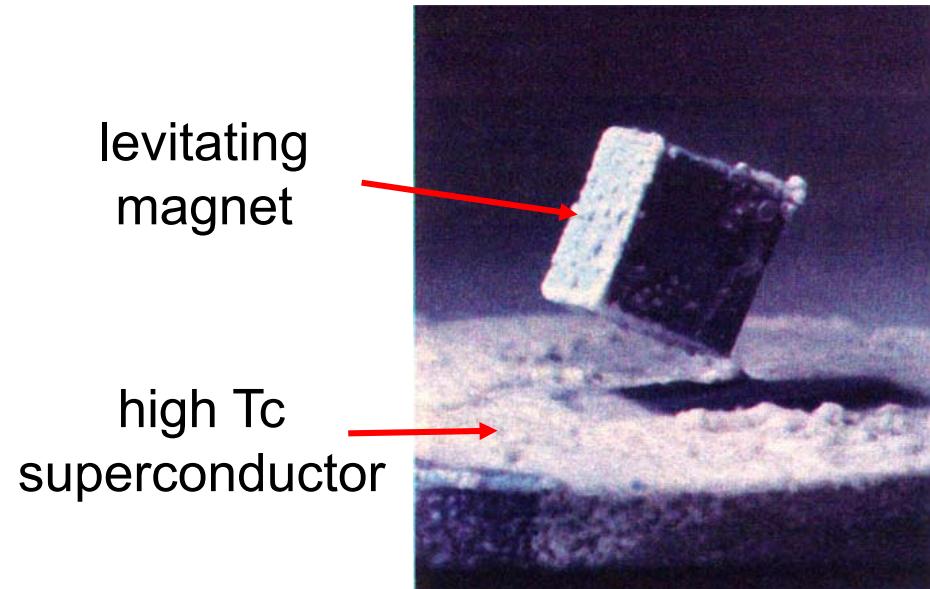


graphene

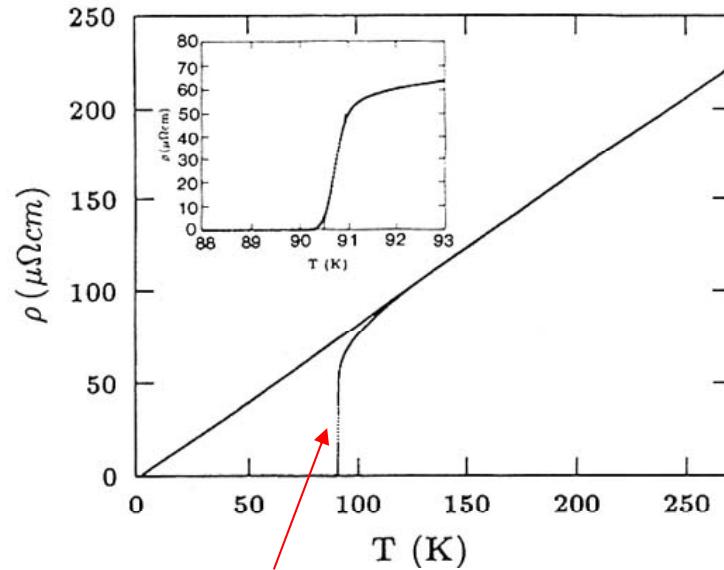


metallic SET

4.5 Interference



Meissner effect
(ideal diamagnetism)

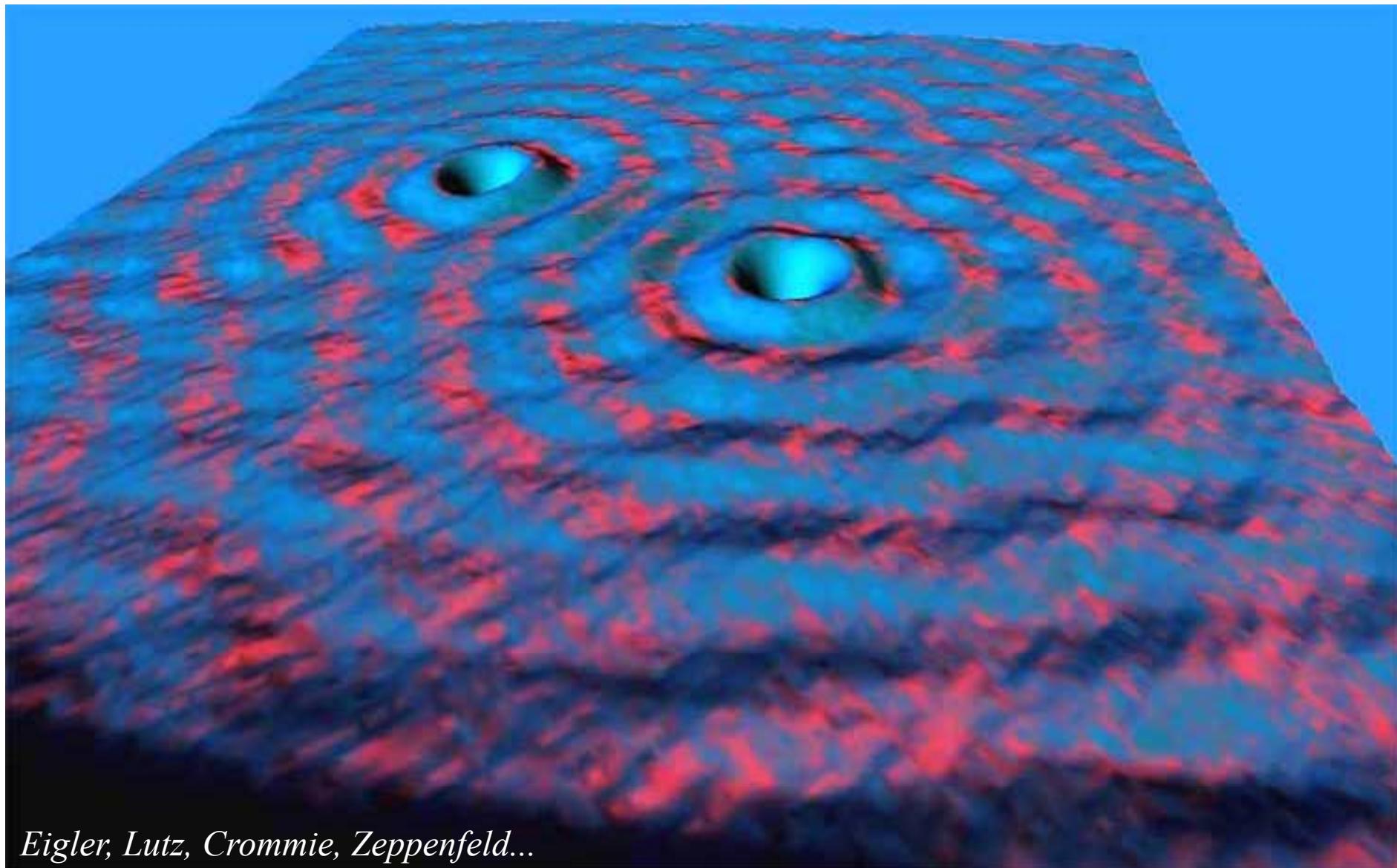


transition to zero resistance

$$\psi = A \exp(i\theta)$$

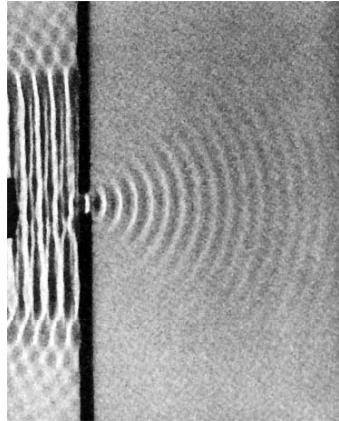
Best known **macroscopic quantum system**: both A and θ are collective „classical“ variables

4.5 Interference

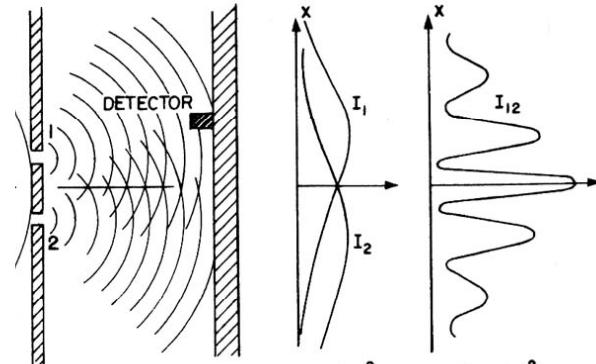


Eigler, Lutz, Crommie, Zeppenfeld...

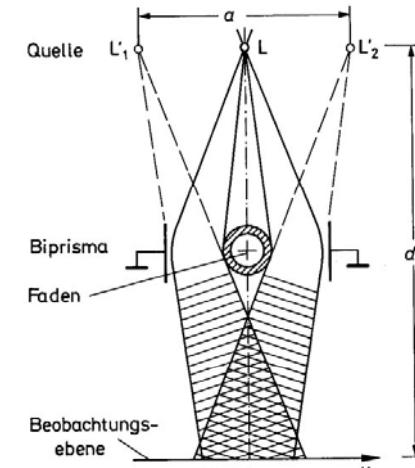
4.5 Interference



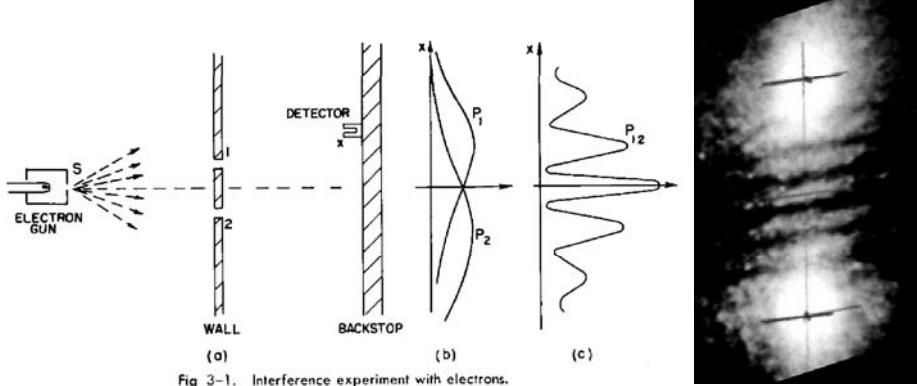
spherical wave



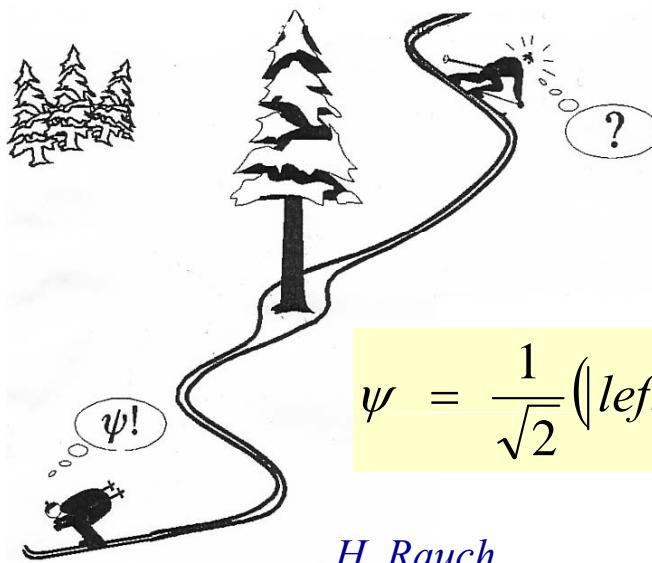
interference of 2 spherical wave
Young's double slit experiment



(Moellenstedt, Tonamura)



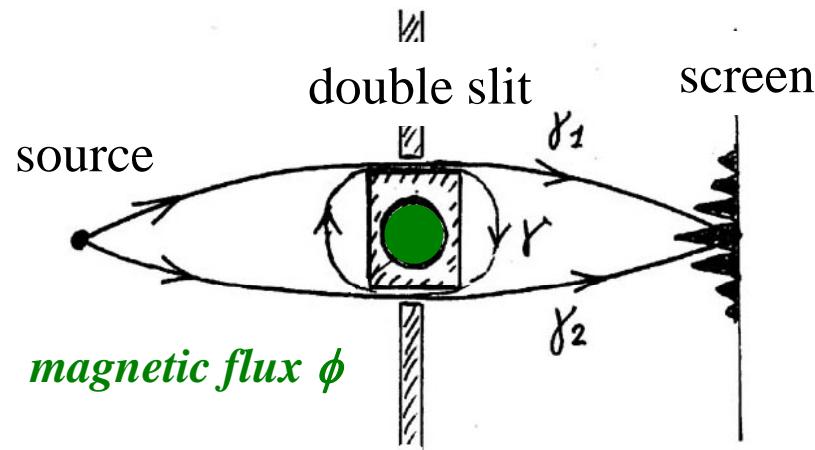
lens-less, low-energy electrons (H.-W. Fink)



$$\psi = \frac{1}{\sqrt{2}} (\lvert left \rangle + \lvert right \rangle)$$

H. Rauch

4.5 Interference Aharanov-Bohm effect



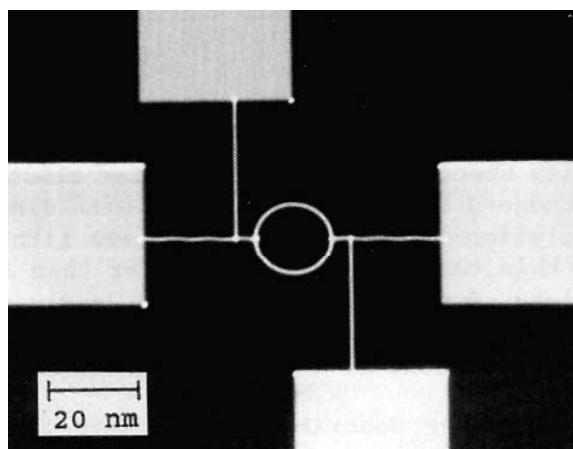
$$\psi = |\psi| \exp(i\theta)$$

$$\theta \rightarrow \theta + \frac{e}{\hbar} \int_{n_i} \vec{A} \cdot d\vec{s} \quad (A = \text{vector potential})$$

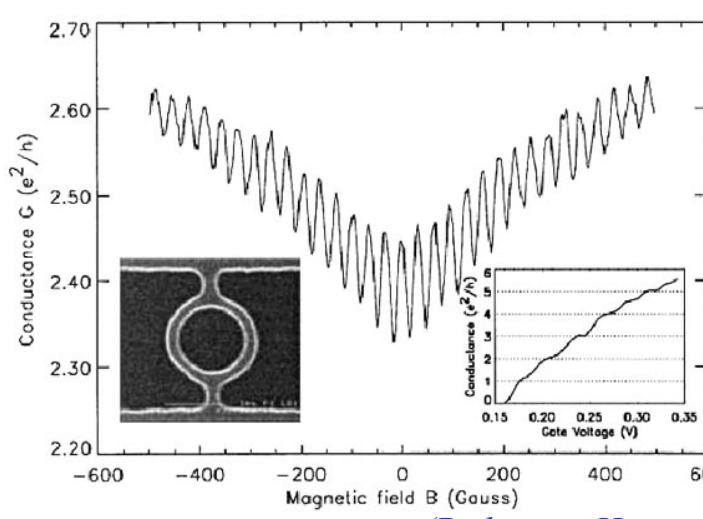
$$\Delta\theta = 2\pi \frac{\phi}{\phi_0}$$

$$\phi_0 = h/e$$

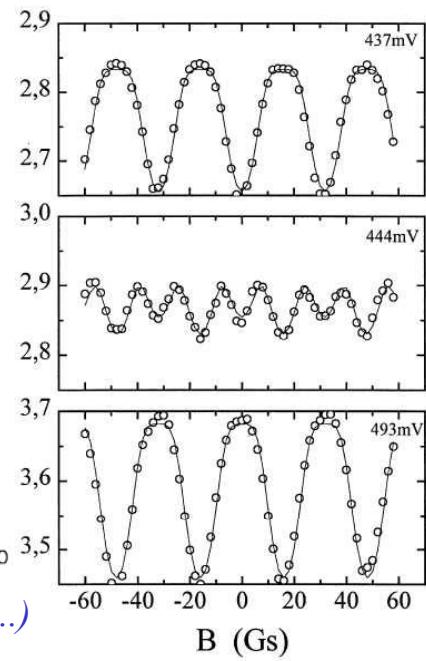
**magnetic
flux
quantum**



(smallest man-made metallic ring)



(Pederson, Hansen...)



4.5 Interference

which path interferometer

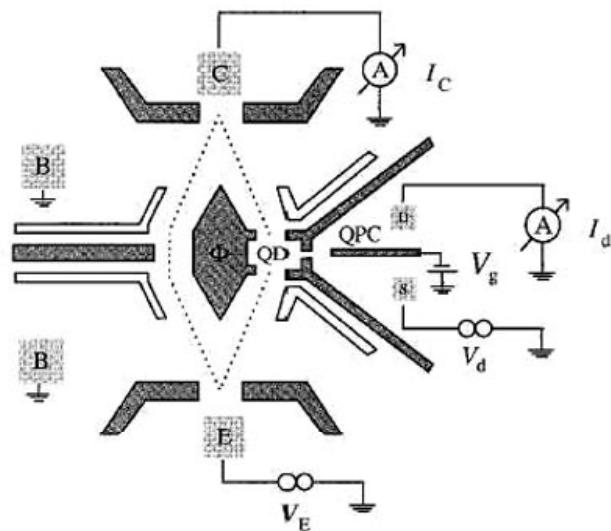
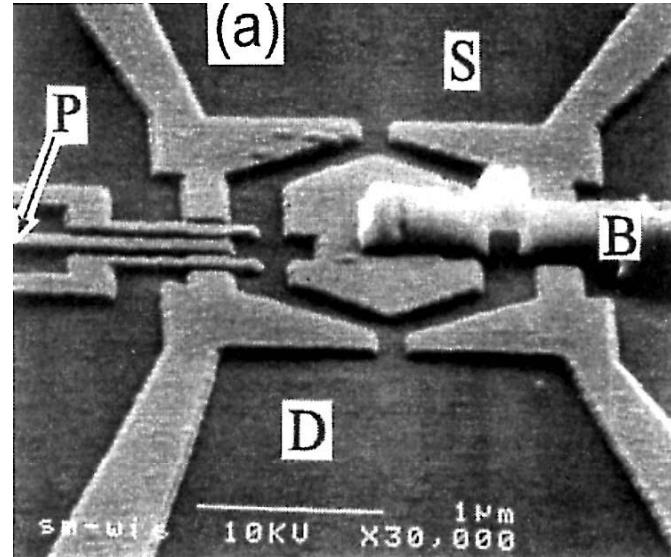
$$\psi = \frac{1}{\sqrt{2}}(|left\rangle + |right\rangle)$$



$$\psi = \frac{1}{\sqrt{2}}(|left\rangle \otimes |O_l\rangle + |right\rangle \otimes |O_r\rangle)$$

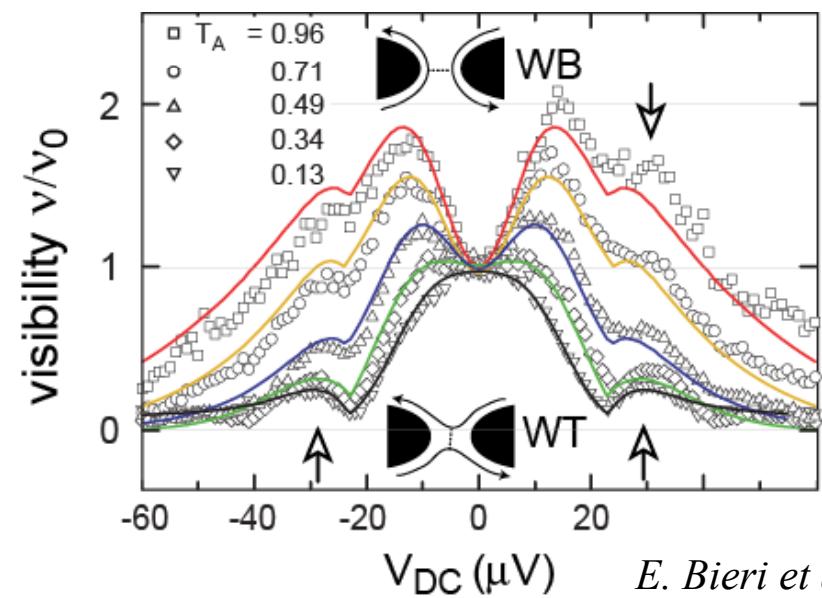
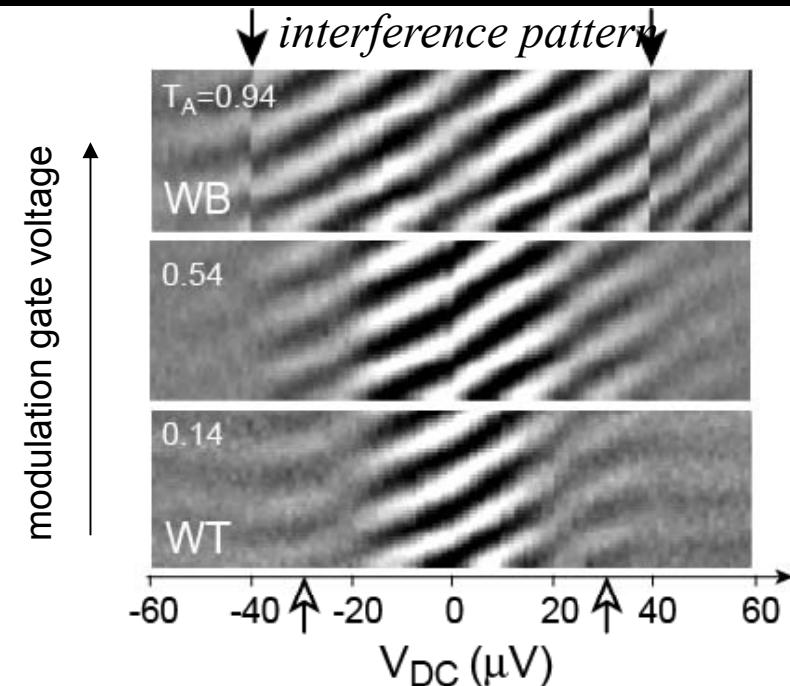
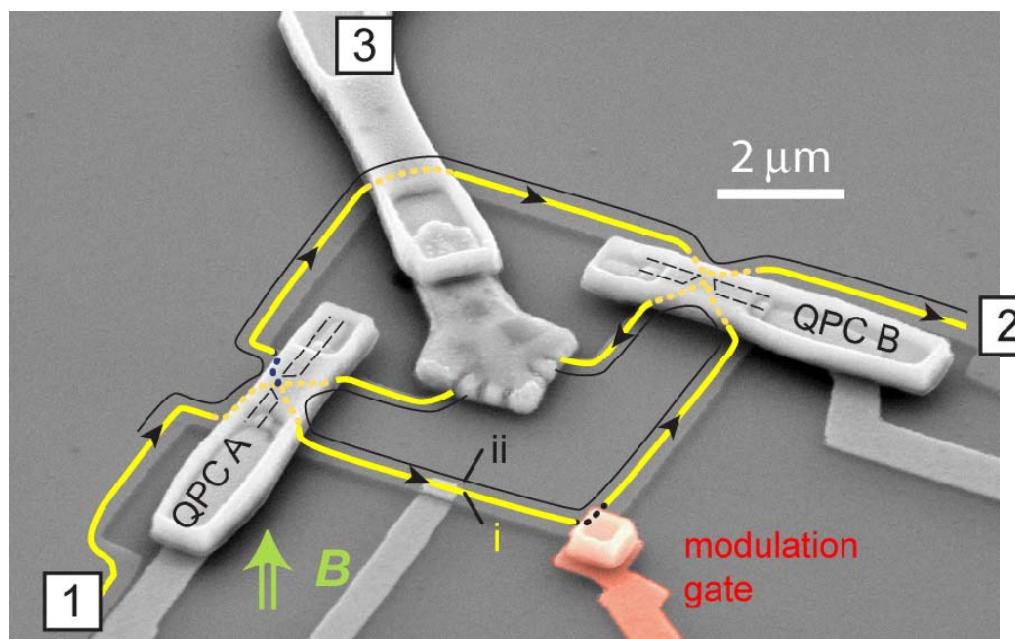
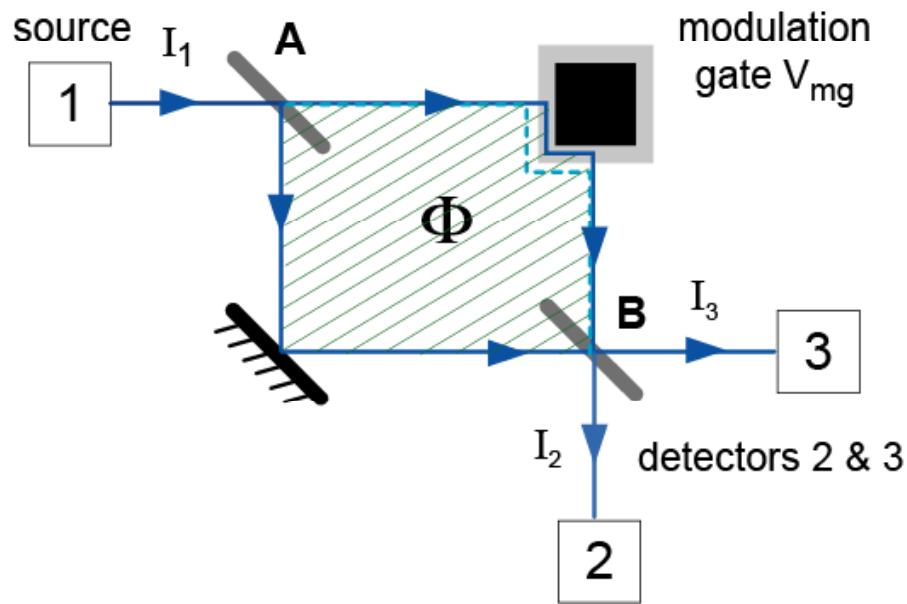
if $\langle O_r | O_l \rangle = 0 \Rightarrow \text{no interference}$

but we know which path the skier took



(Heiblum, Yacoby, Schuster et al. Weizmann)

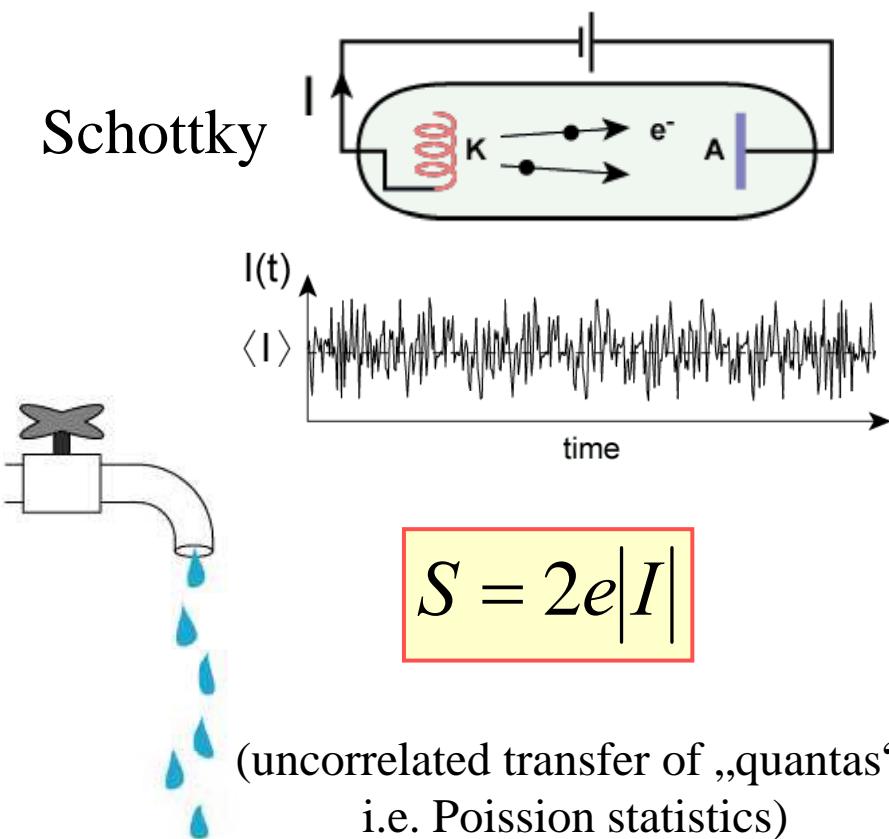
4.5 Mach-Zehnder Interferometer



E. Bieri et al.

4.6 Noise

- A photomultiplier makes **click** if a photon is absorbed.
- Such detectors are not yet available for charge transport in electronics!
- Still, the **granularity** of the measurement process, caused by the **quantization of charge in units of e** , can still be probed.



$$S_{ij}(\omega) = 2 \int dt e^{i\omega t} \langle \Delta I_i(t) \Delta I_j(0) \rangle [A^2 s]$$



Suppression of Shot Noise caused by:

- correlations due to **interactions**
- correlations due to **statistics**
- **fractional charged quasiparticles**

4.7 Quantum computing

4.7 Quantum computing

classical bit b :

$$b \in \{0,1\}$$

b is **either 0 or 1**

quantum bit (qubit) q :

$$q = a|0\rangle + b|1\rangle$$

q is a coherent superposition of 0 **and** 1

different realizations

qubits =

- charge qubit
- flux qubit
- phase qubit
- spin qubit
- trapped ions
- photon qubit

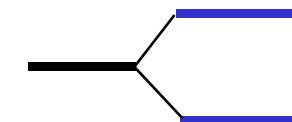
qubit:

qubit is a 2-level system

$$H = E_0|0\rangle\langle 0| + E_1|1\rangle\langle 1| + \frac{E_c}{2}(|0\rangle\langle 1| + |1\rangle\langle 0|)$$

coupling E_c

if $E_1 = E_2$



E.g. prepare state(s)

$$|0\rangle \Rightarrow a|0\rangle + b|1\rangle$$

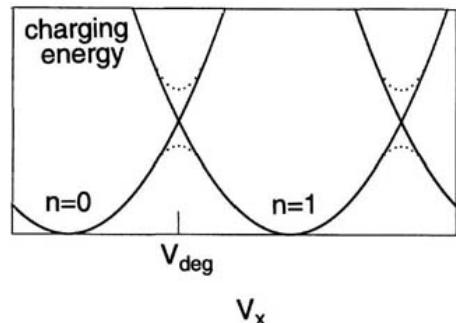
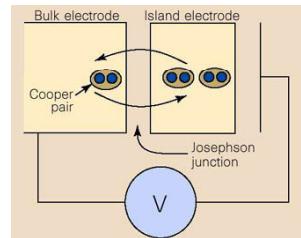
through **control of interaction**
(without loss of coherence..!)

- INTERACTION
- charge
 - current
 - exchange

4.7 Quantum computing

Coherent control of macroscopic quantum states in a single-Cooper-pair box

Y. Nakamura*, Yu. A. Pashkin† & J. S. Tsai*

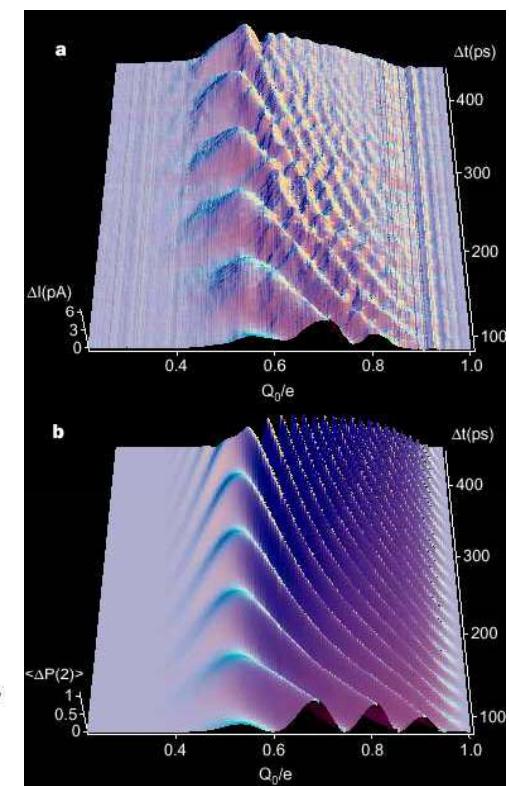
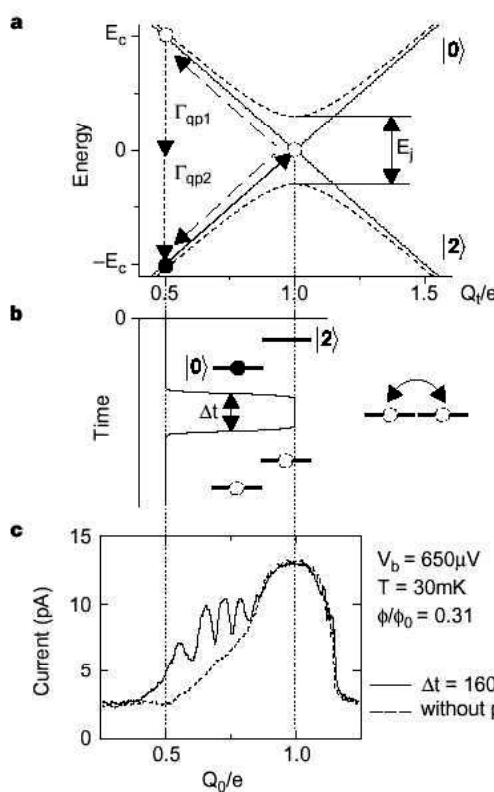
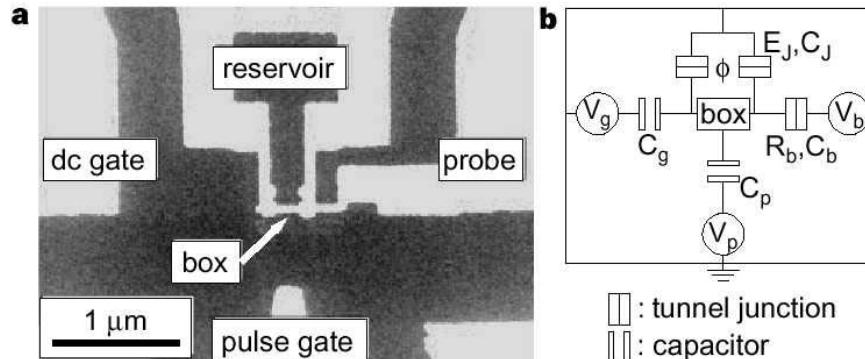


Quantum computation

Solid-state qubits under control

D. V. Averin

?



Quantum Transport FS 2015 / books

books:

- *Transport in Nanostructures*,
M. J. Kelly, Clarendon Press, Oxford
- *Mesoscopic Physics*, Leo Kouwenhoven et al. in
Nato ASI Series E, Vol. 345, p 1-44, Kluwer
- *Mesoscopic Electronics in Solid State Nanostructures*,
Thomas Heinzel, Wieley-VCH
- *Electronic Transport in Mesoscopic Systems*
S. Datta, Cambridge University Press
- *Introduction to Mesoscopic Physics*,
Y. Imry, Oxford University Press
- *The Physics of Low Dimensional Systems*,
J.H. Davies, Cambridge University Press
- *The Physics of Nanoelectronics*
Tero T. Heikkilä, Oxford Master Series
- *Quantum Transport: Introduction to Nanoscience*
Yuli Nazarov and Yaroslav Blanter, Cambridge

Quantum Transport FS 2015 / books

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books:

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M. J. Kelly, Clarendon Press, Oxford
- *Mesoscopic Physics*, Leo Kouwenhoven
Nato ASI Series E, Vol. 345, p 1-44, Kluwer
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- *The Physics of Nanoelectronics*
Tero T. Heikkilä, Oxford Master Series
- *Quantum Transport: Introduction to Nanoscale Electronic Devices*
Yuli Nazarov and Yaroslav Blanter, Cambridge University Press

The Physics of Nanoelectronics

*Transport and Fluctuation Phenomena
at Low Temperatures*

Tero T. Heikkilä



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MASTER SERIES IN CONDENSED MATTER PHYSICS

Basics and 1. exercises

all below you need to know. Repetition on Thursday, but you must prepare yourselves by studying the notes provided, i.e. *1.background_knowledge.pdf*

- Ohm's law, Kirchhoff's laws
- Fermi gas, Fermi parameters like E_F , λ_F , k_F , T_F ...
- band structure (metal and semiconductor, band gap)
- effective mass approximation
- density of states, DOS, $\rho(E_F)$, $N(E_F)$, chemical potential, electrochemical potential
- Schrödinger equation with confining potential in different dimensions
- density of states of Fermi gas in different dimensions
- capacitance spectroscopy (R. Ashoori 1993)
- thermodynamics, Fermi-Dirac and Bose-Einstein distribution
- generalized electron distribution function → week 2

homework 2: read “Quantum Transport in Nano-Structured Semiconductors” by B. Kramer *1.Quantum_Transport_Intro_B.Kramer.pdf*

- how to calculate a current (I do in the class right now !)